PAMS Technical Documentation TFE-2 Series Transceiver

Chapter 2 System Module

CHAPTER 2 – TRANSCEIVER OVERVIEW

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Introduction

The TFE-2 is a radio transceiver unit for the GSM network. It is a GSM power class 4 transceiver providing 15 power levels with a maximum output power of 2 W.

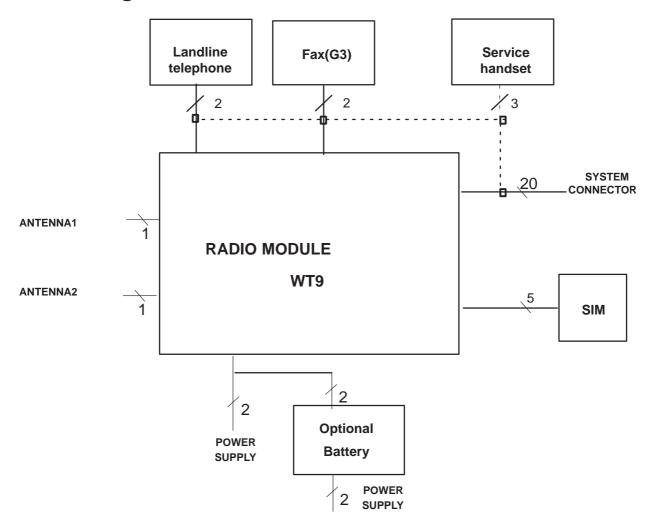
The transceiver consists of a Radio module (WT9) and assembly parts

WT9 is the baseband/RF module TFE–2 cellular transceiver. The WT9 module carries out all the system and RF functions of the transceiver. The system module WT9 is designed for a WLL terminal, that operate in the GSM system.

The small-size SIM (Subscriber Identity Module) card is located inside the phone.

All functional blocks of the system module are mounted on a single multi layer printed circuit board. The chassis of the radio unit has separating walls for baseband and RF. The connections to accessories are taken through the system connector of the radio unit. There is no physical connector between the RF and baseband sections.

Block Diagram of External Connections



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Modes of Operation

There are three different operation modes

- idle mode
- active mode
- local mode

In the idle mode transmitter is in OFF-stage.

In the active mode all the circuits are supplied with power although some parts might be in the idle state part of the time.

The local mode is used for alignment and testing.

Circuit Description

The transceiver electronics consists of one integrated Radio Module (RF + System blocks + LA block). System blocks, RF blocks and LA-block are interconnected with PCB wiring. Accessories are connected to the transceiver via a system connector or 2 RJ-11 connectors.

The System blocks provide the MCU and DSP environments, Logic control IC, memories, audio processing, RF control hardware (RFI2) and 2 to 4 wire interface for the landline telephone. On board power supply circuitry delivers operating voltages for both System and RF blocks. An on–board LA power unit generates feeding voltage and ringing voltage for the landline telephone.

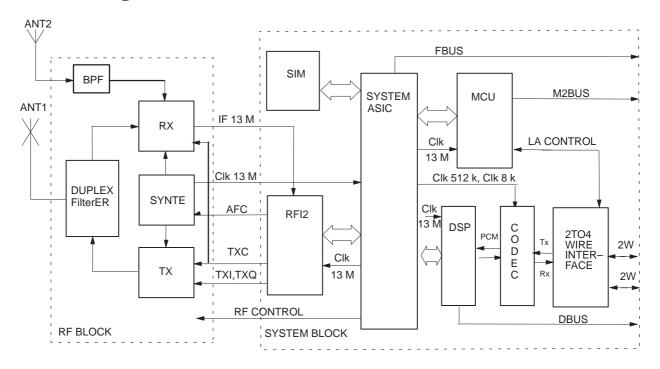
The general purpose microcontroller, Hitachi H3001, communicates with the DSP, memories, and Logic control IC with an 16–bit data bus.

The RF block is designed for a WLL–terminal which operates in the GSM system. The purpose of the RF block is to receive and demodulate the radio frequency signal from the base station and to transmit a modulated RF signal to the base station.

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Block Diagram



Power Distribution

The power supply is based on the ASIC circuit PSCLD. The chip consists of regulators and control circuits providing functions like automatic power up, reset and watchdog functions. External buffering is required to provide more current.

Automatic power up is needed because there is no 'power on' –button on the terminal so whenever power supply is connected to the terminal it will start automatically the power up procedure. If the input voltage is too high or too low, the terminal will automatically shut off, and when the voltage is in the correct window, it will automatically start power–up procedure.

Charging control is not supported.

The detailed power distribution diagrams are given in Baseband blocks and RF blocks documents.

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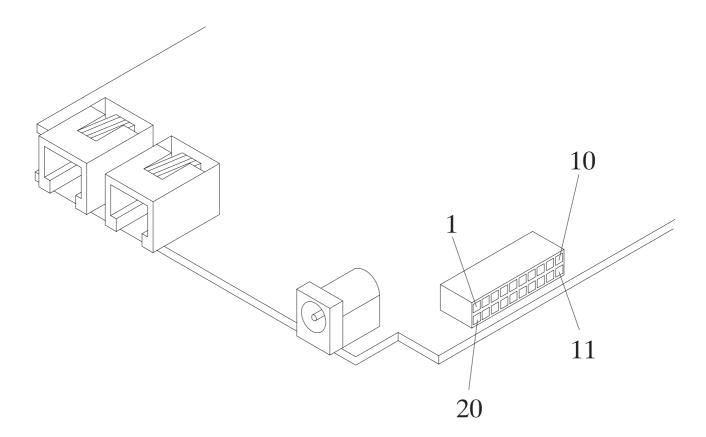
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External Connections

The system module has two connectors, an external system connector, and SIM connector.

System Connector X120



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Accessory Connector

Pin: Name: Description:

| 1 | RS_RX | Serial RX (Receive data for serial communication) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
|----|----------|--|
| 2 | RS_TX | Serial TX (Transmit data for serial communication) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
| 3 | SCK_RTS | Serial Clock (Serial Clock for synchronous communication / RS_RTS) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
| 4 | WDDIS | "0"; min/max 00.6 V Watchdog disable, Flash mode"1"; min/max 2.47.15 V, Normal mode |
| 5 | PCMDCLK | Audio Clock (512 kHz) clock for audio data o "0"; min/max 00.6 V o "1"; min/max 2.43.2 V |
| 6 | MBUS | Serial control bus (General Purpose Control and Test Control Bus) • "0"; min/max 00.5 V • "1"; min/max 2.43.2 V |
| 7 | VPP | Programming Voltage (Programming voltage is applied before entering the programming state) • active; min/max 11.612.6 V • inactive; min/max 03.2 V |
| 8 | DBUS_RXD | DBUS Interface (Receive data for DAI) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
| 9 | DBUS_TXD | DBUS Interface (Transmit data for DAI) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
| 10 | PCMSCLK | Audio Clock (8 kHz slot clock for audio data) • "0"; min/max 00.6 V • "1"; min/max 2.43.2 V |
| 11 | VL | Logic Supply Voltage (3 V Logic voltage) • typical; 3.2 V |
| 12 | FBUS_TX | FBUS TX (FBUS transmit) • "0"; min/max 00.5 V • "1"; min/max 2.43.2 V |
| 13 | FBUS_RX | FBUS RX • FBUS receive "0"; min/max 00.6 V • Pull–up on base band "1"; min/max 2.43.2 V |

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| 14 | VBATT | Battery supply voltage • min/max 6.457.15 V |
|----|----------|---|
| 15 | DGND | Digital ground |
| 16 | RS_CTS | RS232 (Handshake signal for RS-232 serial interface) |
| 17 | HOOK_DTR | Accessory detection • active; min/max 00.5 V • inactive; min/max 2.43.2 V |
| 18 | AGND | Analog ground |
| 19 | XMIC_ID | External Microphone Input (Audio in e.g. service hand- set) • typical 200 mV |
| 20 | XEAR_DSR | External Speaker (Audio out e.g. service handset) |

SIM Connector X300

| Pin: | Name: | Description: |
|--------|-------|--------------|
| Pin: | Name: | Description: |
| 1 111. | Name. | Description. |

| 1 | VSIM | SIM voltage supply • min/typ/max: 4.84.95.0 V |
|---|-------|--|
| 2 | SRES | Reset for SIM |
| 3 | CLK | Clock for SIM data (clock frequency minimum 1 MHz if clock stopping not allowed) |
| 4 | GND | Ground for SIM |
| 6 | SDATA | Serial data for SIM |

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Baseband Block

Introduction

The WT9 module is used in TFE–2 products. The baseband is built around one DSP, System ASIC and the MCU. The DSP performs all speech and GSM/PCN related signal processing tasks. The baseband power supply is 3V, except for the A/D and D/A converters that are the interface to the RF section, and to the comparators in the LAPWRU.

The audio codec is a separate device which is connected to both the DSP and the MCU. The audio codec supports the internal audio from line adapter and external audio from the service handset.

The baseband clock reference is derived from the RF section, and the reference frequency is 13 MHz. A low level sinusoidal wave form is fed to the ASIC which acts as the clock distribution circuit. The DSP is running at 39 MHz using an internal PLL. The clock frequency supplied to the DSP is 13 MHz. The MCU bus frequency is the same as the input frequency. The system ASIC provides both 13 MHz and 6.5 MHz as alternative frequencies. The MCU clock frequency is programmable by the MCU. The baseband uses 13 MHz as the MCU operating frequency. The RF A/D, D/A converters are operated using the 13 MHz clock supplied from the system ASIC

The power supply IC contains three different regulators. The output voltage from each regulator is 3.15V nominal. One of the regulators uses an external transistor as the boost transistor.

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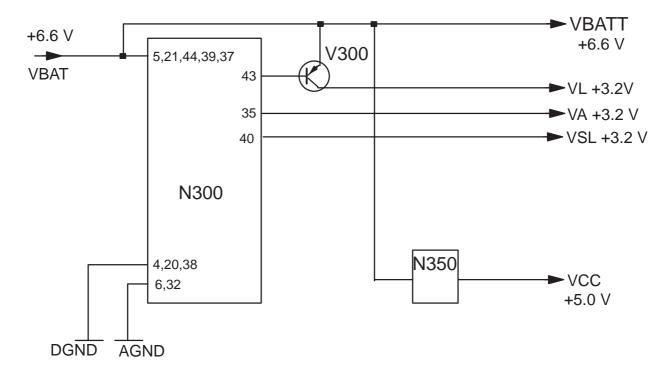
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Modes of Operation

The baseband can operate only in the active mode in WLL terminal.

Circuit Description

Power Supply



The baseband has one power supply circuit N300 delivering power to the different parts in the baseband. There are two logic power supplies and one analog power supply. The analog power supply VA is used for analog circuits such as audio codec. Due to the current consumption and the baseband architecture the digital supply is divided into to parts.

Both digital power supply VSL and VL from the N300 PSCLD are used to distribute the power dissipation inside N300 PSCLD. The main logic power supply VL has an external power transistor, V300 to handle the power dissipation.

D400, ASIC, and the MCU SRAM D440 are connected to the same logic supply voltage. All other digital circuits are connected to the main digital supply. The analog voltage supply is connected to the audio codec.

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Power Supply Regulator PSCLD, N300

The power supply regulators are integrated into the same circuit N300. The power supply IC contains three different regulators. The main digital power supply regulator is implemented using an external power transistor V300. The other two regulators are completely integrated into N300.

PSCLD, N300 External Components

N300 performs the required power—on timing. The PSCLD N300 internal power on and reset timing is defined by the external capacitor C318. This capacitor determines the internal reset delay, which is applied when the PSCLD N300 is initially powered by applying the power supply. The baseband power—on delay is determined by C315. With a value of 10 nF, the power—on delay after a power—on request has been active is in the range of 50—150 ms. C311 determines the PSCLD N300 internal oscillator frequency, and the minimum power—off time when power is switched off.

The sleep control signal from the ASIC D400 is connected via PSCLD N300. During normal operation, the baseband sleep function is controlled by the ASIC D400, but since the ASIC is not powered up during the startup phase, the sleep signal is controlled by PSCLD N300 as long as the PURX signal is active. This arrangement ensures that the 13 MHz clock provided from RF to the ASIC D400 is started and stable before the PURX signal is released, and the baseband exits reset. When PURX is inactive high, the sleep control signal is controlled by the ASIC D400.

N300 requires capacitors on the input power supply as well as on the output from each regulator to keep each regulator stable during different load and temperature conditions. Due to EMC precautions, a Filterer using C301, L302 and L303 has been inserted into the supply rail. This Filterer reduces the high frequency components present at the VBAT from exiting the baseband into the power supply. The regulator outputs also have Filterer capacitors for power supply Filterering and regulator stability. A set of different capacitors are used to achieve a high bandwidth in the suppression Filterer.

PSCLD, N300 Control Bus

The PSCLD N300 is connected to the baseband common serial control bus. This bus is a serial control bus from the ASIC D400 to several devices on the baseband. This bus is used by the MCU to control the operation of N300 and other devices connected to the bus. N300 has two internal 8 bit registers and the PWM register used for charging control. The registers contain information for controlling reset levels, charging HW limits, watchdog timer length, and watchdog acknowledgement.

The control bus includes three wires: clock, serial data, and chip select for each device on the bus. From the PSCLD N300 point of view, the bus can be used for writing only. It is not possible to read data from PSCLD N300 using this bus.

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The MCU can program the HW reset levels when the baseband exits/enters reset. The programmed values are retained until PSCLD N300 is powered off, i.e. the power supply is cut off. At initial power—on, when PSCLD is powered—on, the default reset level is used. The default value is 5.1 V, with the default hysteresis of 400 mV. This means that reset is exit at 5.5 V when the PSCLD N300 is powered for the first time.

The watchdog timer length can be programmed by the MCU using the serial control bus. The default watchdog time is 32 s with a 50 % tolerance. The complete baseband is reset if the watchdog is not acknowledged within the specified time. The watchdog is running while PSCLD N300 is powering—up the system but PURX is active. This arrangement ensures that if for any reason the supply voltage doesn't increase above the reset level within the watchdog time the system is reset by the watchdog. As the time PURX is active is not exactly known, and depends upon startup conditions, the watchdog is internally acknowledged in PSCLD when PURX is released. This allows the MCU always the same time to respond to the first watchdog acknowledgement.

The PSCLD N300 also contains a switch for connecting and the supply voltage to the baseband A/D converters. The switch state can be changed by the MCU via the serial control bus. When PURX is active, the switch is open to prevent the supply voltage from being applied to the baseband measurement circuitry, which is powered off. Before any measurement can be performed, the switch must be closed by MCU.

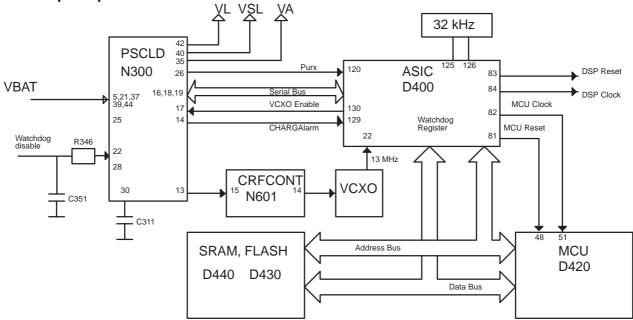
SIM Interface and Regulator in N300

The SIM card regulator and interface circuit is integrated into PSCLD N300. The benefit from this is that the interface circuits are operating from the same supply voltage as the card, avoiding the voltage drop caused by the external switch used in previous designs. The PSCLD N300 SIM interface also acts as voltage level shifting between the SIM interface in the ASIC D400 operating at 3V and the card operating at 5V. Interface control in PSCLD is direct from ASIC, D400 SIM interface. The MCU can select the power supply voltage for the SIM using the serial control bus. The default value is 3V which needs to be changed to 5V before power—up of the SIM interface in ASIC D400. The regulator enable and disable is controlled by the ASIC via SIMI(2).

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Power-On Reset Operation

The system power–up reset is generated by the regulator IC N300. The reset is connected to the ASIC D400 that is reset whenever the reset signal PURX is low. The ASIC D400 then resets the DSP D360, the MCU D420, and the digital parts in N450. When reset is removed, the clock supplied to the ASIC D400 is enabled inside the ASIC. At this point, the 32 kHz oscillator signal is not enabled inside the ASIC, since the oscillator is still in the startup phase. To start up the block requiring 32 kHz clock, the MCU must enable the 32 kHz clock. The MCU reset counter is now started and the MCU reset is still kept active low. A 6.5 MHz clock is started to MCU in order to put the MCU D420 into reset. The MCU is a synchronous reset device, and needs a clock to reset. The reset to MCU is set inactive after 128 MCU clock cycles, and MCU is started.

DSP D360 and N450 reset is kept active when the clock inside the ASIC D400 is started. A13 MHz clock is started to DSP D360 and puts it into reset. D360 is a synchronous reset device, and requires a clock to enter reset. The N450 digital parts are reset asynchronously and do not need a clock to be supported to enter reset.

As both the MCU D420 and DSP D360 are synchronous reset devices, all interface signals connected between these devices and ASIC D400 which are used as I/O are set into input mode on the ASIC D400 side during reset. This avoids bus conflicts occurring before the MCU D420 and the DSP D360 are actually reset.

The DSP D360 and N450 reset signal remains active after the MCU has exited reset. The MCU writes to the ASIC register to disable the DSP reset. This arrangement allows the MCU to reset the DSP D360 and N450 whenever needed. The MCU can put DSP into reset by writing the reset active in the ASIC D400 register

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MCU

The baseband uses a Hitachi H3001 type of MCU. This is a 16-bit internal MCU with 8-bit external data bus. The MCU is capable of addressing up to 16 MByte of memory space linearly, depending upon the mode of operation. The MCU has a non multiplexed address/data bus which means that memory access can be done using less clock cycles thus improving the performance but also tightening up memory access requirements. The MCU is used in mode 3 which means 8-bit external data bus and 16 Mbyte of address space. The MCU operating frequency is equal to the supplied clock frequency. The MCU has 512 bytes of internal SRAM. The MCU has one serial channel, USART that can operate in synchronous and asynchronous mode. The USART is used in the MBUS implementation. The clock required for the USART is generated by the internal baud rate generator. The MCU has 5 internal timers that can be used for timing generation. Timer TIOCA0 input pin 71 is used for generation of the netfree signal from the MBUS receive signal which is connected to the MCU USART receiver input on pin 2.

The MCU contains 4 10-bit A/D converters channels that are used for base-band monitoring.

The MCU, D420 has several programmable I/O ports which can be configured by SW. In this case, the data bus lines D0–D7 are used for baseband control functions. It is not used as part of the data bus.

MCU Access and Wait State Generation

The MCU can access external devices in 2 state access or 3 state access. In two state access the MCU uses two clock cycles to access data from the external device. In 3 state access the MCU uses 3 clock cycles to access the external device or more if wait states are enabled. The wait state controller can operate in different modes. In this case, the programmable wait mode is used. This means that the programmed amount of wait states in the wait control register are inserted when an access is performed to a device located in that area. The complete address space is divided into 8 areas each area covering 2 MByte of address space. The access type for each area can be set by bits in the access state control register. Furthermore, the wait state function can be enabled separately for each area by the wait state controller enable register.

This means that in 3 state access, two types of access can be performed with a fixed setting:

- 3 state access without wait states
- 3 state access with the amount of wait states inserted determined by the wait control register

If the wait state controller is not enabled for a 3 state access area, no wait states are inserted when accessing that area even if the wait control register contains a value that differs from 0 states.

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MCU Flash Loading

The flash loading equipment is connected to the baseband by means of the service adapter. The power supply for the baseband is supplied via the adapter and controlled by the flash programming equipment. The baseband module is powered up when the power is connected to the power supply connector.

Five signals are required for the flash programming, with the addition of the power supply. The baseband MCU will automatically wait for flash down—loading to be performed if one of the two following criteria are met.

- The flash is found to be empty when tested by the MCU
- The serial clock line at the baseband MCU is forced low when the MCU is exiting reset

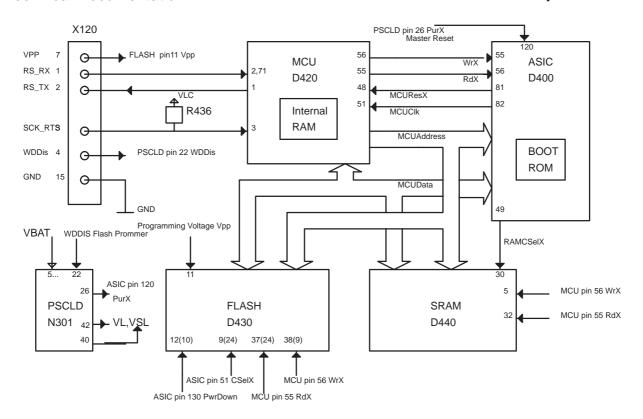
The second alternative is used for reprogramming as the flash is not empty in this case. To allow the serial clock line to be forced low during MCU initial boot there is a requirement that the flash prommer can control the power on of the baseband module. This is done by controlling the switching of the power supply. This arrangement allows the baseband module to operate in normal mode even if the flash prommer is connected but not active. The flash prommer also disables the power supply watchdog during flash programming to prevent unwanted reset of the baseband. The programming voltage to the flash is applied when the flash prommer has detected that the baseband module is powered. This detection is performed by monitoring the serial interface RS_RX line from the baseband. The RS_RX line is pulled high by a pull—up resistor in idle. The VPP voltage is set to 5V as it is not known at this point what type of device is used.

The following diagram shows the block diagram for the baseband flash programming circuitry.

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The interface lines between the flash prommer and the baseband are in low state when power is not connected by the flash prommer. The data transfer between the flash programming equipment and the base band is synchronous, and the clock is generated by the flash prommer. The same MCU USART that is used for MBUS communication is used for the serial synchronous communication. The PSCLD watchdog is disabled when the service adapter and flash prommer are connected.

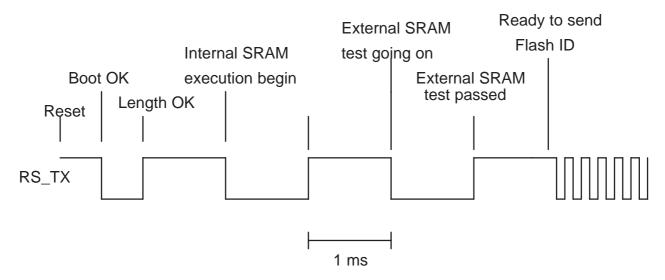
After the service adapter has been connected to the board the power to the baseband module can be connected by the flash prommer or the test equipment. All interface lines are kept low, except for the data transmit from the baseband that is in reception mode on the flash prommer side, this signal is called RS_TX. The MCU boots from ASIC and investigates the status of the synchronous clock line. If the clock input line from the flash prommer is low or no valid SW is located in the flash, MCU forces the initially high RS_TX line low acknowledging to the flash prommer that it is ready to accept data.

The flash prommer sends data length, 2 bytes, on the RS_RX data line to the baseband. The MCU acknowledges the 2 data byte reception by pulling the RS_TX line high. The flash prommer now transmits the data on the RS_RX line to the MCU. The MCU loads the data into the internal SRAM. After having received the transferred data correctly MCU puts the RS_TX line low and jumps into internal SRAM and starts to execute the code. After a guard time of 1 ms the RS_TX line is put high by the MCU. After 1 ms the RS_TX is put low indicating that the external SRAM test is going on. After a further 1 ms, the RS_TX is put high indicating that external SRAM test has passed. The MCU performs

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the flash memory identification based upon the identifiers specified in the Flash Programming Specifications. In case of an empty device, identifier locations shows FFH, the flash device code is read and transmitted to the Flash Prommer.



After that, the device mounted on baseband has been identified, and the Flash Prommer down–loads the appropriate algorithm to the baseband. The programming algorithm is stored in the external SRAM on the baseband module, and after having down–loaded the algorithm and data transfer SW, the MCU jumps to the external SRAM and starts to execute the code.

The MCU now asks the prommer to connect the flash programming power supply. This SW loads the data to be programmed into the flash, and implements the programming algorithm that has been down loaded.

Flash, D430

A 8 MBit Boot Block flash is used as the main program memory D430. The device is 3 V read/program with external 12V VPP for programming. The device has a lockable boot sector. This function is not used since the complete code is reprogrammed. The Boot sector is located at the "bottom", definition by Intel, address 00000H–03FFFH. The block is unlocked by a logic high state on pin 12. This logic high level is generated from VPP. The device can be programmed by a VPP of 5V but the programming procedure takes longer. To improve programming, the programming voltage used is 12V. The speed of the device is 150 ns. The MCU operating at 6.5 MHz will access the flash in 2 state access, requiring 150 ns access time from the memory.

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SRAM D440

The baseband is designed to take two different size of SRAMs, 64kx8 and 128kx8, not at the same time. The required speed is 150 ns as the MCU will operate at 6.5 MHz and the SRAM will be accessed in 2 state access. The SRAM has no battery backup which means that the content is lost even during short power supply disconnections. As shown in the memory map, the SRAM is not accessible after boot until the MCU has enabled the SRAM access by writing to the ASIC register.

EEPROM D445

The baseband is designed to take an 8kx8 serial EEPROM. TFE–2 will use the 8kx8 serial device over the I2C bus. The I2C bus protocol is implemented in SW and the physical implementation is performed on MCU Port 4.

MCU and Peripherals

MCU Port P4 Usage

MCU, D420 port 4 is used for baseband control.

| Port Pin | MCU pin | Control Function | Remark |
|----------|---------|---------------------|------------|
| P40 | 5 | SLIC-CTRL 0 | |
| P41 | 6 | SLIC-CTRL 1 | |
| P42 | 7 | SLIC-CTRL 2 | |
| P43 | 8 | RS_DSR | |
| P44 | 9 | EEPROM SCK | |
| P45 | 10 | EEPROM SDA | |
| P46 | 11 | EEPROM write enable | Active low |
| P47 | 12 | RS_CTS | |

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Baseband A/D Converter Channels usage in N450 and D420

The auxiliary A/D converter channels inside RFI2 N450 are used only for measuring of the system board temperature by the MCU.

The MCU has 4 10 bit A/D channels which are used for baseband voltage monitoring. The MCU can measure supply voltage, accessory detection (ID), loop current (IBBDET) and line apapter power supply voltage (VBBDET) by using it's own converters.

Baseband N450 A/D Converter Channel Usage

Name: Usage: Input volt. range

| Chan 0 | System board temperature | 03.2 V |
|----------|--------------------------|--------|
| Chan 1-7 | not used | |

MCU Baseband A/D Converter Channel Usage

Name: Usage: Input volt. range

| Chan 0 | Supply voltage | 03.2 V |
|--------|---------------------|--------|
| Chan 1 | Accessory detection | 03.2 V |
| Chan 2 | IBBDET | 03.2 V |
| Chan 3 | VBBDET | 03.2 V |

Supply Voltage Measurement

The supply voltage is measured using MCU N420 A/D converter channel 0. The supply voltage supplied to the A/D converter input is switched off when the baseband is powered off. The supply voltage measurement voltage is supplied by PSCLD N300, which performs switch—off, and scaling with a scaling factor of R1(R1+R2). The measurement voltage is Filterered by a capacitor to achieve an average value that is not depending upon the current consumption behavior of the baseband. To be able to measure the supply voltage during transmission pulse, the time constant must be short. The value for the Filterering capacitor is set to 10 nF C316. The scaling factor used to scale the supply voltage must be 1:3, which means that a 9V supply voltage will give 3V A/D converter input voltage. The A/D converter value in decimal can be calculated using the following formula:

A/D = $1023xR1xU_{BAT}/((R1+R2)xU_{ref}) = 1023xU_{BAT}xK$ where K is the scaling factor. K = $R1/((R1+R2)xU_{ref})$.

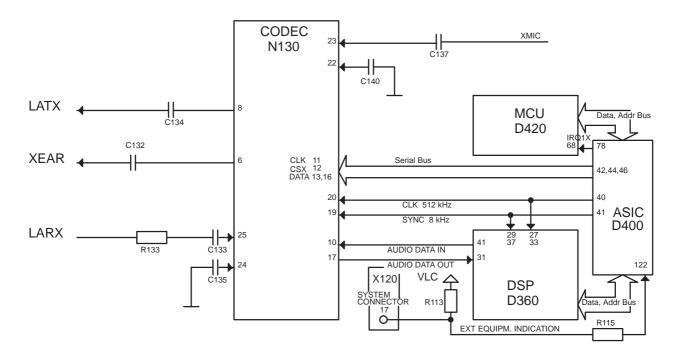
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Audio Control

The audio codec N130 is controlled by the MCU D420. The ASIC generates a 512 kHz data clock, and a 8 kHz synchronization signal for the PCM data bus. Data is put out on the bus at the rising edge of the clock and read in at the falling edge. Data from the DSP D360 to the audio codec N130 is transmitted as a separate signal from data transmitted from the audio codec, N130 to the DSP D360. The communication is full duplex synchronous. The transmission is started at the falling edge of the synchronization pulse. 16 bits of data is transmitted after each synchronization pulse.



The 512 kHz clock is generated from 13 MHz using a PLL type of approach, which means that the output frequency varies as the PLL adjusts the frequency. The average frequency is 512 kHz. The clock is not supplied to the codec when it is not needed. The clock is controlled by both MCU and DSP. DTMF tones are generated by the audio codec and for that purpose, the 512 kHz clock is needed. The MCU must switch on the clock before the DTMF generation control data is transmitted on the serial control bus.

The serial control bus uses clock, data, and chip select to address the device on the bus. This interface is built into the ASIC, and the MCU writes the destination and data to the ASIC registers. The serial communication is then initiated by the ASIC. Data can be read form the audio codec N130 via this bus.

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DSP

The DSP used in TFE–2 is the TI 320LC546. This is a 16 bit DSP that can use external and/or internal memory access. The DSP can operate in two modes microprocessor mode or micro–controller mode. The difference between the two modes is that in microprocessor mode the DSP boots from external memory, while in the micro–controller mode the DSP boots from internal ROM. The DSP external memory access is divided into data, program, and I/O access. The type of access is indicated on three control pins that can be used for memory control.

The DSP D360 executes code from the internal ROM. The baseband also provides external memories for the DSP, D371, D372, D381, and D382 (Note: These memories are not fitted in all transceivers). The DSP is capable of addressing 64 kword of memory. The memory area is divided into a code execution area and a data storage area. The code execution area is located at address 4000H–FFFFH in the internal ROM. The external memories are arranged in such a way that the DSP can access the external memories both as data storage and code execution. The memory chip select is taken from the memory access strobe signal from the DSP. This means that the memory is active during any memory access. The SRAMs are configured in chip select controlled write mode. This means that both the write signal and the output enable signal are active at the same time, and the actual write occurs at the rising edge of the chip select signal. This implementation is required since the DSP supports only one signal for write/read control.

The DSP is operating from the 13 MHz clock. In order to get the required performance, the frequency is internally increased by a PLL by a factor of 3. The PLL requires a settling time of 50 us after that the clock has been supplied before proper operation is established. This settling counter is inside the DSP although the ASIC D400 contains a counter that will delay the interrupt with a programmable amount of clock cycles before the interrupt causing the clock to be switched on is presented to the DSP. The DSP has full control over the clock supplied to it. When the DSP is to enter the sleep mode the clock is switched off by setting a bit in the ASIC register. The clock is automatically switched on when an interrupt is generated.

The DSP also has two synchronous serial channels for communication. One channel is used for data transmission between the DSP and the audio codec. This channel is operating at 512 kbits, and clock and synchronization signal is provided by the ASIC D400. The other channel is used for debugging purposes, and uses the same clock and synchronization signals. The DSP has an interrupt controller servicing four interrupts and one non maskable interrupt, NMI. The interrupts have fixed priority which can only be changed by changing the interconnection between the interrupt sources by HW.

The ASIC contains DSP support functions as modulator, encryption/decryption using algorithms A5/A51, RF power ramp generation/AGC control, AFC control, synthesizer serial interface, frame counters, timer, RFI2 interface, and RX and TX power control timing. The RF power ramp timing/AGC control, AFC control,

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and synthesizer control are timed to the value of the frame counter. This means that data is loaded into the registers, and transferred when the frame counter and the reference values match. This allows timing of the synthesizer control power ramp and start of TX data to be controlled very precisely.

As the receiver and the transmitter is not operating at the same time, the TX power ramp function is used to control the AGC in the receiver during the reception. This requires the DSP to continuously modify the values in the TX ramp SRAM to fit the ramp during TX and the AGC value during reception.

DSP ASIC Access

The DSP is accessing the ASIC in the DSP I/O area. 2 wait states are required for the ASIC access. Some of the DSP registers located in the ASIC are retimed to the internal ASIC clock and requires special handling with respect to consecutive writing. This means that the same register can not be written again until a specified time has passed. To cope with this, DSP is inserting NOP instructions to satisfy this requirement.

DSP Interrupts

The DSP supports 4 external interrupts. Three interrupts are used. The ASIC, D400 generates two of the interrupts. One interrupt is generated by the RFI2 N450 auxiliary A/D converter. This interrupt is generated when a baseband measurement A/D conversion is completed. The interrupts to the DSP are active low.

INTO, which is the highest priority interrupt, is used for data reception from the receiver and is generated by the ASIC. The INT1 signal is used for auxiliary A/D channel conversions generated by the RFI2. This interrupt is generated by RFI2 and is a result of measurement requests from the DSP. INT3 is a low priority interrupt generated by the ASIC timer. The DSP programs the timer value and an interrupt is given when the timer expires. The interrupt must be active at least 1 DSP clock cycle as it is sampled on the rising/falling edge by the DSP. All interrupts are active low.

Unused interrupt controller inputs are tied high.

DSP Serial Communications Interface

The DSP contains two synchronous serial communications interfaces. One of the interfaces is used to communicate with the audio codec N130. The 512 kHz clock required for the data transfer is provided by D400 as well as the 8 kHz synchronization signal. Data is transferred on to lines, RX and TX creating a full duplex connection. Data is presented on the bus on the first rising edge of the clock after the falling edge of the synchronization pulse. Data is read in by each device on the falling edge of the clock. Data transfer is 16 bits after each synchronization pulse.

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The DSP D360 has control over the clock provided to the audio codec. The DSP can switch on the clock to start the communication, and switch it off when it is not needed. This clock is also under control of MCU D420.

RF Synthesizer Control

The synthesizer control is performed by the DSP D360 using the ASIC D400 as the interfacing and timing device. Different synthesizer interfaces are supported, and the required interface can be selected by the DSP at the initialization stage of the ASIC. The synthesizer interface also includes timing registers for programming synthesizer data. The DSP loads the synthesizer data into the transmission registers in the ASIC synthesizer interface together with the timing information. The system timing information is used for synthesizer data loading. When the system timing register, frame counter, value matches the timing value programmed into the synthesizer interface, the interface transmits the loaded data to the RF synthesizer, and the VCO frequency is changed accordingly. As the synthesizer may be powered off when not needed, the interface pins towards the synthesizer can be put in tri–state or forced low when the interface is not active.

RFI2 N450 Operation

The RFI2 N450 contains the A/D and D/A converters to perform the A/D conversion from the received signal and the D/A converters to perform the conversion for the modulated signal to be supplied to the transmitter section. In addition, the RFI2 chip also contains the D/A converter for providing AFC voltage to the RF section. This AFC voltage controls the frequency of the 13 MHz VCXO which supplies the system clock to the baseband. The RFI2 N450 also contains the D/A converter to control the RF transmitter power control. The power control values are stored in the ASIC D400 and at the start of each transmission, the values are read from the ASIC D400 to the D/A converter producing the power control pulse. This D/A converter is used during the reception to provide AGC for the receiver RF parts.

The RFI2 contains the interface between the baseband and the RF. The RFI2 circuit contains the A/D converters required for the receiver and the D/A converters required for the transmission. In addition, the RFI2 contains a 10 bit D/A converter for AFC control, and one of the receiver A/D converters has a multiplexed input for 8 additional channels used for baseband monitoring functions. The A/D converters are 12 bit sigma delta type. This means that the digital output is centered around the reference voltage and the output value is both negative and positive. The RFI2 has an internal reference voltage for the A/D and D/A converters that can be switched off to save power. The reference has external Filterering capacitors to improve the converter performance. The transmitter D/A converters are followed by interpolator and post Filterer. The Filterer is of switch capacitor type and the Filterer parameters are taken into account when modulator parameters are calculated. The AFC D/A converter is static

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and requires no clock for operation. This means that the RFI2 clock can be switched off and the AFC value will be kept.

One of the A/D converters used for receiver signal conversion can be used as an auxiliary converter that supplies 8 channels for baseband measurement purposes. When the converter is used in this mode, each conversion generates an interrupt directly to the DSP. The DSP operates this converter via the ASIC D400.

Data communication between the ASIC D400 and RFI2 N450 is carried out on a 12 bit parallel data bus. The ASIC D400 uses 4 address lines to access RFI2 N450. Depending on the direction of the communication, either the write control signal is used to write data to RFI2 N450 or the read signal is used to read data from RFI2 N450. The ASIC D400 supplies 13 MHz clock to the RFI2 N450. This clock is used as reference for the A/D and D/A converters. Communication between the ASIC D400 and the RFI2 N450 is related to the clock.

The auxiliary channels supported by the RFI2 uses one of the receiver A/D converters as the A/D converter. Due to the type of converter used for the receiver converters, the value read from the auxiliary channels can be negative. The input voltage applied to the auxiliary channels must be within 0.5–3.0 V. A 12 bit value is received from the auxiliary channel measurement. The auxiliary channel conversion complete is sent direct to the DSP as an interrupt, INT1. The DSP reads the value using direct access through the ASIC to the RFI2 converter. The conversion is started by the DSP writing the address of the channel to be measured to the ASIC register. The ASIC then writes the selected channel to RFI2, and the conversion is started. The DSP may sample the same channel for more than one value as the A/D converter will produce continuously new values. Several samples may be used for example in supply voltage measurement to calculate an average value from the results.

The RFI2 N450 digital supply is taken from the baseband main digital supply. The analog power supply, 4.5V is generated by a regulator supplied from the RF section. The analog power supply is always supplied as long as the baseband is powered, if R311 is assembled. The RFI2 N450 analog power supply can be switched off during sleep by removing R311 and adding R312. In this case the RFI2 N450 analog power supply is in the control of the PSCLD N300 sleep control signal.

Receiver Timing and AGC

RF receiver power on timing is performed by the ASIC D400. The DSP D360, can program the time when the receiver is to be powered on. The timing information is taken from the system timing that is based upon the frame counter inside the ASIC D400, which is synchronized to the base station carrier frequency using AFC to tune the receiver. As transmission and reception takes place at different times, the D/A converter used for transmitter power control is used to control the AGC of the receiver during reception. This requires the DSP D360 to alter the content of the SRAM containing the information that is written to the D/A converter for the reception and the transmission.

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RF Transmitter Timing and Power Control

The RF Power Amplifier (PA) timing control is performed by the ASIC D400. The power control is performed by the ASIC D151 using the D/A converter in N450. The ASIC D400 controls the power supply voltage to the RF transmitter sections. As the first step, the relevant circuits are powered on using the TX power control output from the ASIC D400. The timing for powering on the TX circuits is generated from the ASIC internal system timing circuitry, frame counter. As the RF TX circuits need time to stabilize after power on before the actual transmitter can be started, there is a programmable delay before the ASIC D400 starts to write the power ramp data to the D/A converter inside N450. The TXC signal which is generated in this way controls the power ramp of the PA and the power level for that burst. At the end of the burst the power ramp is written to the D/A converter inside N450. The data that creates the power ramp and final power level is stored in a SRAM inside the ASIC D400. At the start of the ramp, the contents of the SRAM are read out in increasing address order. At the end of the ramp the contents are read out in decreasing address order. The power level during the burst is determined by the last value in the SRAM, this value is the value that will remain in the D/A converter during the burst. The DSP D360 may change the shape of the falling slope of the power ramp by writing new values to the power ramp SRAM during the burst.

As the transmitter may have to adjust the transmitter burst due to the distance from the base station there is an additional timer for this purpose. This timing is called the timing advance and will cause the transmission to start earlier when the distance to the base station increases.

SIM Interface

The SIM interface is the serial interface between the smart card and the baseband. The SIM interface logic levels are 5V, but the baseband is designed in such a way that a 3V technology SIM can be used whenever it is available. The SIM interface signals are generated inside the ASIC. The signals coming from the ASIC are converted to 5V levels. The PSCLD circuit is used as the logic voltage conversion circuit for the SIM interface. The PSCLD circuit also contains the voltage regulator for the SIM power supply. The control signals from the ASIC to PSCLD are at 3V level and the signals between PSCLD and the SIM are 3V or 5V levels, depending on the SIM. An additional control line between the ASIC and the PSCLD is used to control the direction of the DATA buffer between the SIM and the PSCLD. In a 3V technology environment this signal is internal to the ASIC only. The pull up resistor required on the SIM DATA line is integrated into the PSCLD, and the pull-up is connected to the SIM regulator output inside PSCLD. In idle, the DATA line is kept as input by both the SIM and the interface on the baseband. The pull-up resistor is keeping the DATA line in it's high state.

The power up and power down sequences of the SIM interface are performed according to ISO 7816–3. To protect the card from damage when the power supply is removed during power on, there is a control signal, CARDIN, that au-

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tomatically starts the power down sequence. The CARDIN information is taken from 5 V regulator N350.

Since the power supply to the SIM is derived from PSCLD also using 3V technology SIM, the power supply voltage of the SIM regulator is programmable 3.15/4.8 V. The voltage is selected by using the serial control bus to PSCLD. The default value is set to 3.2V nominal.

For cross compatibility reasons, the interface is started up using 3V. A 5V SIM will not operate at 3V. The supply voltage is switched to 5V if the SIM cannot accept 3V. The SIM has a bit set in a data field indicating it's capability of 3V operation.

The regulator control signal is derived from the ASIC, and this signal controls the operation of the SIM power supply regulator inside PSCLD. To ensure that the powered off ASIC doesn't cause any uncontrolled operations at the SIM interface, the PSCLD signals to the SIM are forced low when the PURX signal is active low. This implementation will ensure that the SIM interface can not be activated by any external signal when PSCLD has PURX active. When PURX goes inactive the control of the interface signals are given back to the ASIC signals controlling PSCLD SIM interface operations.

The clock to the SIM can be switched off if the SIM card allows stopping of the clock. The clock can be stopped either in high or low state, determined by the card data. For cards not allowing the clock to be stopped there is a 1.083 MHz clock frequency that can be used to reduce the power consumption while the clock is running. In this case the VCO must be running all the time. When the clock is stopped, and the status of the CARDIN signal changes, power is switched OFF, the clock to the SIM is restarted inside the ASIC, and the SIM power down sequence is performed.

To be able to handle current spikes as specified in the SIM interface specifications, the SIM regulator output from PSCLD must have a ceramic capacitor of 100 nF connected between the output and ground close to the SIM interface connector. To be able to cope with the fall time requirements and the disconnected contact measurements in type approval, the regulator output must be actively pulled down when the regulator is switched off. This active pull–down must work as long as the external battery is connected and the battery voltage is above the PSCLD reset level.

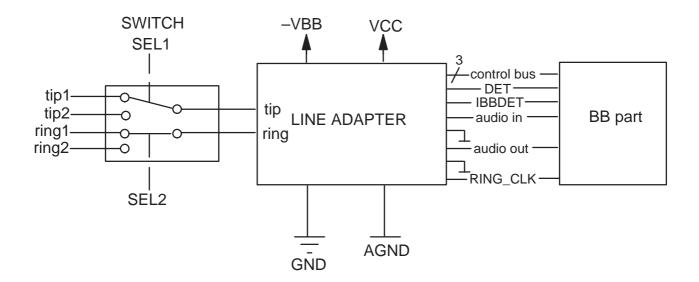
The SIM power on procedure is controlled by the MCU. The MCU can power up the SIM only if the CARDIN signal is in the inactive state low. Once the power up procedure has been started, the ASIC takes care that the power up procedure is performed according to ISO 7816–3.

The SIM interface uses two clock frequencies 3.25 MHz or 1.625 MHz during SIM communication. The data transfer speed in the SIM GSM session is specified to be the supplied clock frequency/372. The ASIC SIM interface supplies all the required clock frequencies as well as the required clock frequency for the UART used in the SIM interface data transmission/reception.

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Line Adapter



The Line Adapter makes 2 to 4—wire transformation between the termination and the base part of the terminal. The 2—wire interface is of balanced line type, and the voltage between tip and ring lines is about 40 V. The 4—wire part is a normal audio—input (LATX) and audio—output (LARX) interface. The line Adapter is based on an Am79R79 SLIC circuit. It is controlled by the MCU with a 3 V parallel bus (3 bits). SLIC uses three different states: ringing, active, and standby. The MCU can detect the termination state (ON—HOOK/OFF—HOOK) by the DET pin. Ringing and metering are done via the RING_CLK line. In ringing state, the MCU feeds 25 Hz to RINGIN pin. The circuit operates with two different operating voltages: VCC (+ 5 V) and –VBB (– 50 V or – 60 V), and with two grounds GND and AGND. Loop current, Hook threshold, and ring waveform are set by discrete components connected to circuits pins RDC, RD, and RINGIN. Loop current can be detected with the IBBDET line, which is connected to BB part.

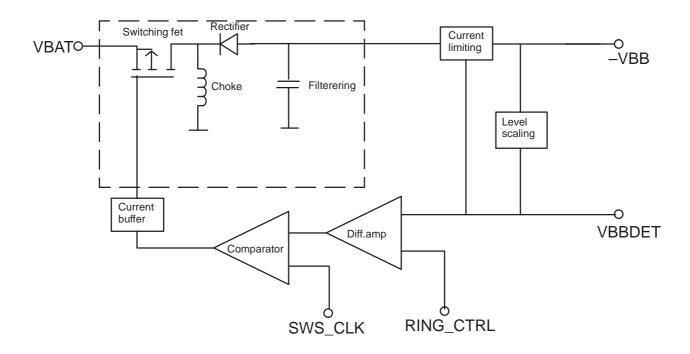
The 2-wire line is divided to two separate 2 wire lines, tip1-ring1 (telephone), and tip2-ring2 (fax machine). The divider is implemented with fet switches, and both lines can be switched on or off separately. Control is made by the MCU with SEL1 and SEL2 lines. Both 2 wire lines are protected by transient voltage suppressors (82 V) connected from each line to ground.

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Line Adapter Power Supply



The Line Adapter power supply unit is of inverting switch mode power supply type with PWM control. Voltage and current limitation are implemented in the feedback. The main clock signal SWS_CLK is made by MCU, and it is 125 kHz square wave. With RING_CTRL line output voltage can be increased from $-50\,$ V to $-60\,$ V when SLIC is in ringing state. The VBBDET line is used to detect output voltage level. Current limitation is set to about 50 mA.

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RF Block

Introduction

The RF module carries out all the RF functions of the transceiver. This module works in the GSM system.

Components are located on one side of the PCB.

EMC leakage is prevented with metallized shield A on side one, and metallized shield B on side two. Both shields also conduct heat out of the inner parts of the phone, thus preventing excessive temperature rise.

Receiver

The receiver system is based on double conversions. There is also space diversity in this receiver. Space diversity is created by using two separate RX antennas and partially separated signal routes.

The received RF signal from the antenna is fed via a duplex Filterer or receiver Filterer to the receiver unit. The signal is amplified by a discrete low noise preamplifier. The gain of the amplifier is controlled by the AGC control lines (ANT1SEL/ANT2SEL). The nominal gain of 21 dB is reduced about 48 dB. After the preamplifier the signal is Filterered by SAW RF Filterer. The Filterer rejects spurious signals coming from the antenna and spurious emissions coming from the receiver unit.

The Filterered RF signal is down converted by a passive diode mixer. The frequency of the first IF is 71 MHz in GSM. The first local signal is generated by the UHF synthesizer. The first IF signal is amplified and then it is Filterered by SAW Filterer. The Filterer rejects adjacent channel signal, intermodulating signals and the last IF image signal.

The Filterered IF signal is fed to the receiver part of the integrated RF circuit CRFRT. In CRFRT the Filterered IF signal is amplified by an AGC amplifier which has gain control range of 57 dB. The gain is controlled by an analog signal via TXC-line.

The amplified IF signal is down converted to the last IF in the mixer of CRFRT. The last local signal is generated from VHF VCO by dividing the original signal by 4 in the dividers of CRFRT.

The last IF frequency is 13 MHz. The last IF is Filterered by a ceramic Filterer. The Filterer rejects signals of the adjacent channels. The Filterered last IF is fed back to CRFRT where it is amplified and fed out to RFI via RXINN and RXINP –lines.

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Frequency Synthesizers

The stable frequency source for the synthesizers and base band circuits is a discrete voltage controlled crystal oscillator VCXO. The frequency of the oscillators is controlled by an AFC voltage, which is generated by the base band circuits.

The UHF PLL generates the down conversion signal for the receiver and the up conversion signal for the transmitter. The UHF VCO is a discrete oscillator. The working assumption for PLL circuit is Philips UMA1018.

The VHF PLL signal (divided by 4 in CRFRT) is used as a local for the last mixer. Also the VHF PLL signal (divided by 2 in CRFRT) is used in the I/Q modulator of the transmitter chain.

Transmitter

The TX intermediate frequency is modulated by an I/Q modulator contained on transmitter section of CRFRT IC. The TX I and Q signals are generated in the RFI interface circuit and they are fed differentially to the modulator.

Modulated intermediate signal is amplified or attenuated in temperature compensated controlled gain amplifier (TCGA). The output of the TCGA is amplified and the output level is typically –15dBm.

The output signal from CRFRT is band–pass Filterered to reduce harmonics and the final TX signal is achieved by mixing the UHF VCO signal and the modulated TX intermediate signal with passive mixer. After mixing the TX signal is amplified and Filterered by two amplifiers and one Filterer. This Filterer is dielectric Filterer. After these stages the level of the signal is typically 0.65 mW (–2 dBm).

The discrete power amplifier amplifies the TX signal to the desired power level. The maximum output level is typically 2.0 W.

The power control loop controls the output level of the power amplifier. The power detector consists of a directional coupler and a diode rectifier. Transmitted power is controlled with controlled gain amplifier (TCGA) on TX-path of CRFRT. Power is controlled with TXC and TXP signals. The power control signal (TXC), which has a raised cosine form, comes from the RF interface circuit, RFI.

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RF Characteristics

Receiver

| ITEM | GSM |
|---|----------------------------------|
| RX frequency range , MHz | 935960 |
| Туре | 2 IFs linear |
| Intermediate frequencies , MHz | 71, 13 |
| 3 dB bandwidth ,kHz | +/- 100 |
| Reference noise bandwidth ,kHz | 270 |
| Sensitivity , dBm | -104 S/N ratio > 8 dB BN=135 kHz |
| AGC dynamic range dB | 105 |
| Receiver gain ,dB | 83 typ. |
| RF front end gain control range,dB | 48 |
| 2nd IF gain control range, dB | 57 |
| Input dynamic range ,dBm | -10410 |
| Gain relative accuracy in receiving band dB | +/- 1.5 |
| Gain relative accuracy on channel ,dB | +/- 0.4 |

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System Module

Pre-Filterers

The duplex Filterer consists of two functional parts; RX and TX Filterers. The TX Filterer rejects the noise power in the RX frequency band and TX harmonic signals. The RX Filterer rejects blocking and spurious signals coming from the antenna.

For diversity use, there is a separate RX Filterer, which rejects blocking and spurious signals coming from antenna 2.

Pre-amplifier

The bipolar pre–amplifier amplifies the received signal coming from the antenna. In the strong field conditions the gain of the amplifier is reduced 36 dB typically.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------------|---------|----------------------|---------|--------------|
| Frequency band | (| 935–960 | | MHz |
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | 10 | 12 | 14 | mA |
| Insertion gain | 19 | 21 | 22 | dB |
| Gain flatness | | +/- 0.5 | | dB |
| Noise figure | | 1.2 | 1.5 | dB |
| Reverse isolation | 15 | | | dB |
| Gain reduction | 45 | 48 | 51 | dB |
| IIP3 | -6 | -3 | | dBm |
| Input VSWR (Zo=50 ohms) | | | 2.0 | |
| Output VSWR (Zo=50 ohms) | | | 2.0 | |

RX Interstage Filterer

The RX interstage Filterer is a SAW Filterer. The Filterer rejects spurious and blocking signals coming from the antenna. It rejects the local oscillator signal leakage.

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First mixer

The first mixer is a single balanced passive diode mixer. The local signal is balanced by a printed circuit transformer. The mixer down converts the received RF signal to IF signal.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------|------------|----------------------|---------|--------------|
| RX frequency range | 935 | | 960 | MHz |
| LO frequency range | 1006 | | 1031 | MHz |
| IF frequency | | 71 | | MHz |
| Conversion loss | 5 | 6 | 7 | dB |
| IIP3 | 4 | 6 | | dBm |
| LO–RF isolation | 15 | | | dB |
| LO power level | - 5 | -3 | | dBm |

First IF amplifier

The first IF amplifier is a bipolar transistor amplifier.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|---------------------|---------|----------------------|---------|-------------------------|
| Operation frequency | | 71 | | MHz |
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | | 32 | 35 | mA |
| Insertion gain | 18 | 20 | 22 | dB |
| Noise figure | | 3.0 | 4.0 | dB |
| IIP3 | 3 | 5 | | dBm |
| Input impedance | | | | matched to the mixer |
| Output impedance | | | | matched to the Filterer |

First IF Filterer

The first IF Filterer is a SAW Filterer. The IF Filterer rejects some spurious and blocking signals coming from the front end of the receiver. The IF Filterer makes the part of the channel selectivity of the receiver. It rejects adjacent channel signals (except the 2nd adjacent).

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System Module

Receiver IF Circuit, RX part of CRFRT

The receiver part of CRFRT consists of an AGC amplifier of 57 dB gain, a mixer and a buffer amplifier for the last IF. The mixer of the circuit down converts the received signal to the last IF frequency. After external Filterering the signal is amplified and fed to baseband circuitry. The supply current can be switched OFF by an internal switch, when the RX is OFF.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|---------------------------------------|---------|----------------------|---------|--------------|
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | | 32 | 44 | mA |
| Input frequency range | 45 | | 87 | MHz |
| Local frequency range of mixer | 170 | | 400 | MHz |
| 2nd IF range | 2 | | 17 | MHz |
| Voltage gain of AGC amplifier | 47 | | | dB |
| Noise figure | | | 16 | Max gain |
| AGC gain control slope | 40 | 84 | 100 | dB/V |
| Mixer output 1dB compression point | | 1.0 | | Vpp |
| Gain of the last IF buffer | | 30 | | dB |
| Max output level after last IF buffer | | 1.6 | | Vpp |

Last IF Filterer

The last IF is 13 MHz. The ceramic Filterer on the last IF provides part of the channel selectivity of the receiver.

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Transmitter

| Item | GSM |
|-------------------------|--------------|
| TX frequency range | 890915 MHz |
| Туре | Upconversion |
| Intermediate frequency | 116 MHz |
| Maximum output power | 2 W (33 dBm) |
| Gain control range | 20 dB |
| Maximum RMS phase error | 5 deg. |

Modulator Circuit TX, part of CRFRT

The modulator is a quadrature modulator contained in Tx–section of CRFRT IC. The I– and Q– inputs generated by RFI interface are DC–coupled and fed via buffers to the modulator. The local signal is divided by two to get accurate 90 degrees phase shifted signals to the I/Q mixers. After mixing the signals are combined and amplified with temperature compensated controlled gain amplifier (TCGA). Gain is controlled with power control signal (TXC). The output of the TCGA is amplified and the maximum output level is typically –10 dBm.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|-------------------------------|---------|----------------------|---------|--------------|
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Supply current | | 35 | 45 | mA |
| Transmit Frequency Input | Minimum | Typical / Nominal | Maximum | Unit / Notes |
| LO input frequency | 170 | | 400 | MHz |
| LO input power level | | 0.2 | | Vpp |
| LO input resistance | 70 | 100 | 130 | ohm |
| LO input capacitance | | 4 | | pF |
| Modulator Inputs (I/Q) | Minimum | Typical / Nominal | Maximum | Unit / Notes |
| Input bias current (balanced) | | | 100 | nA |
| Input common mode voltage | 2.05 | 2.2 | 2.4 | V |
| Input level (balanced) | | | 1.1 | Vpp |
| Input frequency range | 0 | | 300 | kHz |
| Input resistance (balanced) | 200 | | | kohms |
| Input capacitance (balanced) | | | 4 | pF |

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| Modulator Output | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------------------|---------|----------------------|---------|------------------|
| Output frequency | 85 | | 200 | MHz |
| Available linear RF power | | -10 | | dBm, ZiL=50 ohms |
| Available saturated RF power | | 0 | | dBm, ZiL=50 ohms |
| Total gain control range | 45 | | | dB |
| Gain control slope | | 84 | | dB/V |
| Suppression of 3rd order prods | 35 | | | dB |
| Carrier suppression | | 35 | | dB |
| Single sideband suppression | | | | dB |

| Modulator Output | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--|--------------|----------------------|------------|--------------|
| Noise floor | | | -135 | dBm/Hz avg. |
| Transmitted I/Q phase balance drift in whole temperature range | -5 -2 | | 5 2 | deg |
| Transmitted I/Q amplitude balance drift in whole temperature range | -0.5 -0.2 | | 0.5 0.2 | dB |

Up-conversion Mixer

The upconversion mixer is a single balanced passive diode mixer. The local signal is balanced by a printed circuit transformer. The mixer up—converts the modulated IF signal coming from quadrature modulator to RF signal.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------|---------|----------------------|---------|--------------|
| TX frequency range | 890 | | 915 | MHz |
| LO frequency range | 1006 | | 1031 | MHz |
| IF frequency | | 116 | | MHz |
| Conversion loss | 6.0 | 7.0 | 8.0 | dB |
| IIP3 | 0.0 | | | dBm |
| LO – RF isolation | 15.0 | | | dB |
| LO power level | -5.0 | -3.0 | 0.0 | dBm |

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1st TX Buffer

The TX buffer is a bipolar transistor amplifier. It amplifies the TX signal coming from the upconversion mixer.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------------|---------|----------------------|---------|----------------------|
| Operating freq. range | 890 | | 915 | MHz |
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | | 4.5 | 5.0 | mA |
| Insertion gain | 8.0 | 9.0 | 10.0 | dB |
| Input VSWR (Zo=50 ohms) | | | 2.0 | matched to the mixer |
| Output VSWR (Zo=50 ohms) | | | 2.0 | |

TX interstage Filterers

The TX Filterers reject the spurious signals generated in the upconversion mixer. They reject the local, image and IF signal leakage and RX band noise, too.

2nd TX Buffer

The TX buffer is a bipolar transistor amplifier. It amplifies the TX signal coming from the first interstage Filterer.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--------------------------|---------|----------------------|---------|--------------|
| Operating freq. range | 890 | | 915 | MHz |
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | 14 | 15 | 16 | mA |
| Insertion gain | 12.0 | 13.0 | 14.0 | dB |
| Input VSWR (Zo=50 ohms) | | | 2.0 | |
| Output VSWR (Zo=50 ohms) | | | 2.0 | |

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Power Amplifier

The power amplifier is a three stage discrete amplifier. It amplifies the $-2~\mathrm{dBm}$ TX signal to the desired 33 dBmoutput level. It has been specified for 6.8 volts operation.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|-------------------------------------|---------|----------------------|------------|------------------|
| DC supply voltage (no RF) | | | 10 | V |
| DC supply voltage (normal) | 5.5 | 6.8 | 8.0 | V |
| DC supply current | 750 | | 1290 | mA |
| Operating freq range | 890 | | 915 | MHz |
| Operating temp range | | | 90 | deg C |
| Output power | 34.5 | 35.0 | 36.0 | dBm normal cond |
| Output power | 33.0 | 34.0 | 35.0 | dBm extreme cond |
| Input power | 0 | | | dBm |
| Gain | 36.0 | 37.0 | 38.0 | dB normal cond |
| Efficiency | | 42 | | % Po = 35 dBm |
| Input VSWR (Zo=50 ohms) | | | 2.0 | |
| Output VSWR (Zo=50 ohms) | | | 2.0 | |
| Harmonics: 2 fo 3 fo, 4 fo, 5 fo | | | -30 -40 | dBc Po=35 dBm |

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Power Control Circuits

The power control loop consists of a power detector and a differential control circuit. The power detector is a combination of a directional coupler and a diode rectifier. The differential control circuit compares the detected voltage and the control voltage (TXC) and controls voltage controlled amplifier (in CRFRT) or the power amplifier. The control circuit is a part of CRFRT.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|----------------------------|---------|----------------------|----------|--------------|
| Supply voltage using CRFRT | 4.275 | 4.5 | 4.725 | V |
| Supply current using CRFRT | | 3.0 | 5.0 | mA |
| Power control range | 20 | | | dB |
| Power control inaccuracy | | | +/ - 1.0 | dB |
| Dynamic range | 80 | | | dB |
| Input control volt range | 0.2 | | 3.0 | V |

Reference Oscillator

In GSM the reference oscillator is a discrete VCXO and the frequency is 13 MHz in product. The oscillator signal is used for a reference frequency of the synthesizers and the clock frequency for the base band circuits.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--|---------|----------------------|----------------|--|
| Center frequency | | 13 | | MHZ |
| Frequency tolerance | -18 | | 18 | ppm Vc=2.2 V |
| Frequency control range | | 67 | | ppm |
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Current consumption | | 1.5 | 2 | mA |
| Output voltage | 1.3 | 1.7 | 2.0 | Vpp sine wave for PLL |
| Harmonics | | | 5 | dBc |
| Control Voltage Range | 0.3 | | 3.7 | V |
| Nominal Voltage (center freq) | | 2.0 | | V |
| Control Sensitivity | 12 | 16 | 22 | ppm/V |
| Frequency stability, vs. temperature vs. supply voltage vs. load vs. aging | | | 10 1 0.1 | ppm, -25+70 deg.C ppm, 4.7 V +/- 5 % ppm, load +/- 10 % ppm, year |
| Operating temperature range | -20 | | 70 | deg. C |
| Load impedance: resistive part | 2 | | | kohm |
| parallel capacitance | | | 20 | pF |

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VHF PLL

The VHF PLL consists of the VHF VCO, PLL integrated circuit and loop Filterer. The output signal is used for the 2nd mixer of the receiver and for the I/Q modulator of the transmitter.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|---|---------|--|--|--------------|
| Start up settling time | | | 5 | ms |
| Phase error | | | 1 | deg. rms |
| Sidebands offset from carrier +/- 200 kHz +/- 400 kHz +/- 1M Hz +/- 2 MHz +/- 3 MHz > 4 MHz | | -75 -84 <-85 <-85 <-85 <-85 | -70 -70 -70 -75 -85 -85 | dBc |

VHF VCO + Buffer

The VHF VCO uses a bipolar transistor as a active element and a combination of a chip coil and varactor diode as a resonance circuit. The buffer is combined into the VCO circuit so, that they use same collector current.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|--|---------|----------------------|----------------------|----------------------------|
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Control voltage | 0.5 | | 4.0 | V |
| Supply current | | 4.0 | 5.0 | mA |
| Operation frequency | | 232 | | MHz |
| Output power level | | 168 | | mV _{rms} / 1 kohm |
| Control voltage sensitivity | | 12 | | MHz/V |
| Phase noise fo +/- 200 kHz fo +/- 1600 kHz fo +/- 3000kHz | | | -123 -133 -143 | dBc/Hz |
| Harmonics | | -32 | -30 | dBc |

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UHF PLL

The UHF PLL consists of a UHF VCO, divider, PLL circuit and a loop Filterer. The output signal is used for the 1st mixer of the receiver and the upconversion mixer of the transmitter.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|---|---------|----------------------------|--------------------------|--------------|
| Start up settling time | | | 5 | ms |
| Phase error | | | 4 | deg. rms |
| Settling time +/- 93 MHz | | 525 | 800 | us |
| Sidebands offset from carrier +/- 200 kHz +/- 400 kHz +/- 600 kHz > 1.0 MHz | | -80 -87 <-90 <-90 | -60 -65 -70 -80 | dBc |

UHF VCO + Buffer

The UHF VCO uses a bipolar transistor as a active element and a combination of a microstripline and a varactor diode as a resonance circuit.

UHF VCO Buffers

The UHF VCO output signal is divided into the 1st mixer of the receiver and the upconversion mixer of the transmitter. The UHF VCO signal is amplified after division. There is one buffer for TX and one for RX.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|------------------|---------------------------|----------------------|---------|----------------------------|
| Supply voltage | 4.275 | 4.5 | 4.725 | V |
| Supply current | 6 | 7 | 8 | mA |
| Frequency range | see UHF VCO specification | | | MHz |
| Input power | | -3 | | dBm |
| Harmonics | | | -10 | dBc |
| Output amplitude | | 1000 | | mV _{rms} / 1 kohm |

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System Module

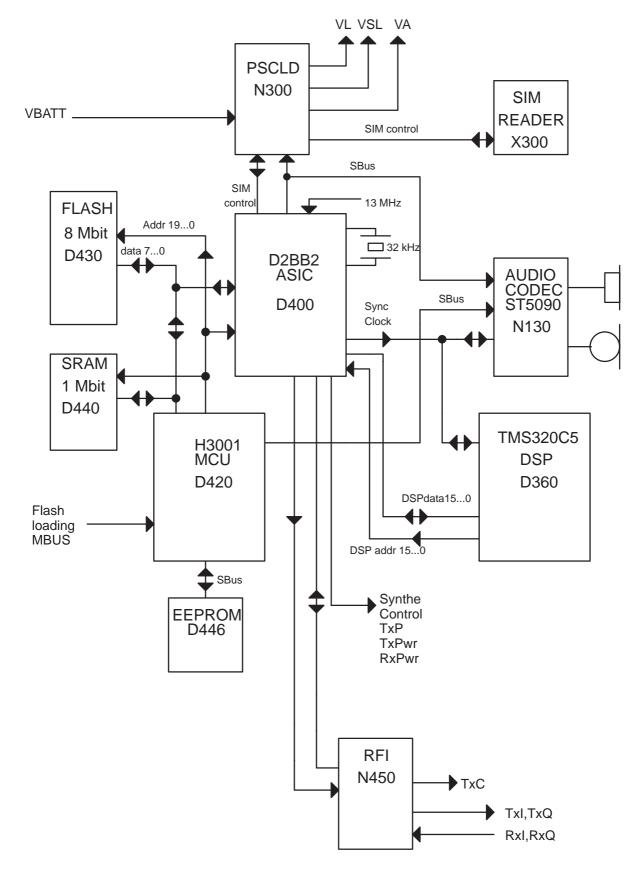
PLL Circuit

The PLL circuit is a dual frequency synthesizer including both the UHF and VHF synthesizers.

| Parameter | Minimum | Typical / Nominal | Maximum | Unit / Notes |
|---------------------------|-------------------------|----------------------|---------------|--|
| Supply voltage | 2.7 | | 5.5 | V |
| Supply current | | 10.0 | | mA |
| Principal input frequency | 500 | | 1200 | MHz Vdd = 4.5 V |
| Auxiliary input frequency | 20 | | 300 | MHz Vdd = 4.5 V |
| Input reference frequency | 3 | | 40 | MHz, Vdd = 4.5 V |
| Input signal level | 50 -10 -15 500 | | 500 4 4 | mV rms dBm main divider dBm aux. divider mVpp ref. divider |

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Interconnection Diagram of Baseband

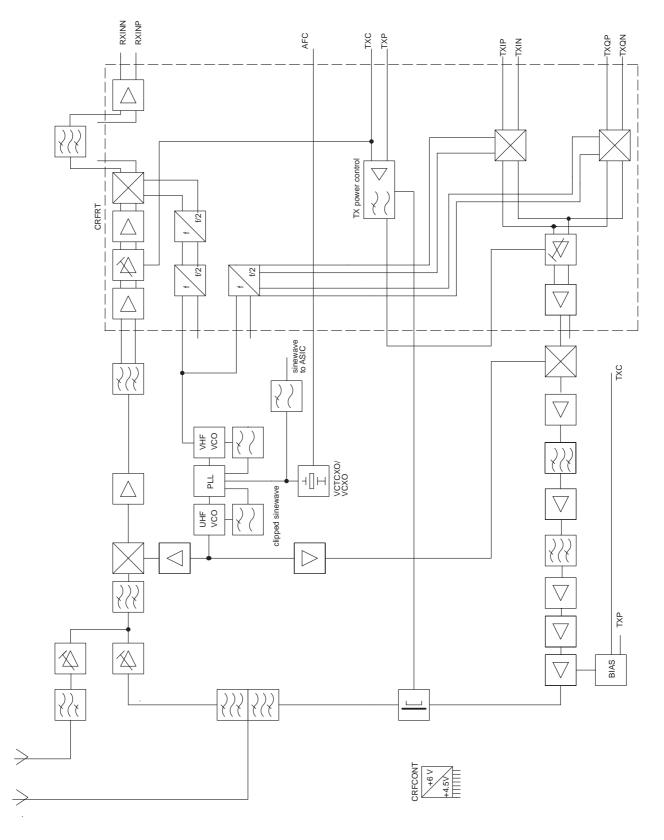


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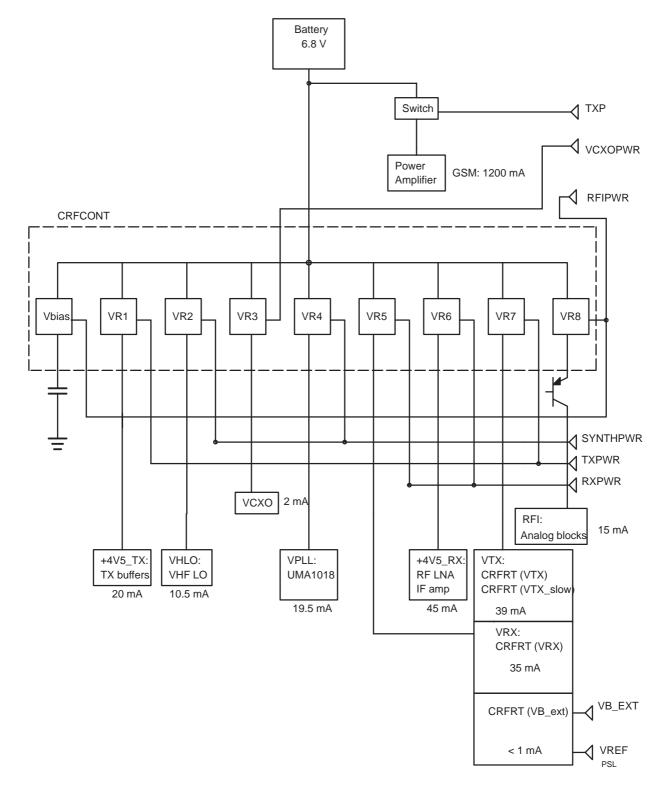
System Module

Block Diagram of RF



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Power Distribution Diagram of RF



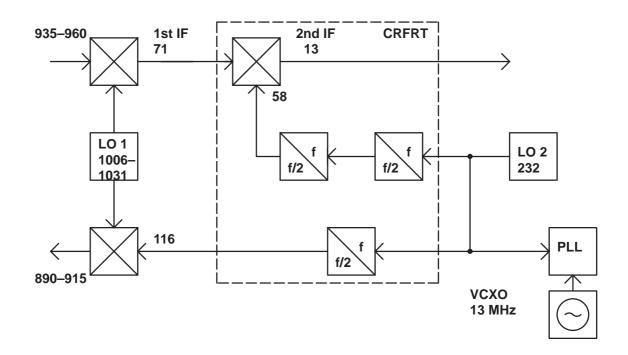
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RF Frequency Plan

GSM



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| 3 | Circuit Diagram ofLine Adapter Power Supply | 3/A3-3 |
| 4 | Circuit Diagram of 2 to 4 Wire Ilterface | 3/A3-4 |
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Parts list of WT9

| | (EDMS Iss | ue 2.3) | | | Code: 0201147 |
|------|-----------|---------------|-------|-----------|---------------|
| ITEM | CODE | DESCRIPTION | | VALUE | TYPE |
| R100 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 | W 0603 |
| R110 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 | W 0603 |
| R111 | 1430065 | Chip resistor | 10 k | 5 % 0.063 | W 0603 |
| R112 | 1430167 | Chip resistor | 47 | 5 % 0.063 | W 0603 |
| R113 | 1430051 | Chip resistor | 4.7 k | 5 % 0.063 | W 0603 |
| R114 | 1430167 | Chip resistor | 47 | 5 % 0.063 | W 0603 |
| R115 | 1430065 | Chip resistor | 10 k | 5 % 0.063 | W 0603 |
| R123 | 1430167 | Chip resistor | 47 | 5 % 0.063 | W 0603 |
| R124 | 1430167 | Chip resistor | 47 | 5 % 0.063 | W 0603 |
| R125 | 1430167 | Chip resistor | 47 | 5 % 0.063 | W 0603 |
| R126 | 1430051 | Chip resistor | 4.7 k | 5 % 0.063 | W 0603 |
| R127 | 1430065 | Chip resistor | 10 k | 5 % 0.063 | W 0603 |
| R128 | 1430001 | Chip resistor | 100 | 5 % 0.063 | W 0603 |
| R129 | 1430087 | • | 100 k | 5 % 0.063 | W 0603 |
| R131 | 1430087 | Chip resistor | 100 k | 5 % 0.063 | W 0603 |
| R132 | 1430071 | Chip resistor | 22 k | 5 % 0.063 | W 0603 |
| R133 | 1430087 | • | 100 k | 5 % 0.063 | W 0603 |
| R134 | 1430043 | Chip resistor | 2.2 k | 5 % 0.063 | W 0603 |
| R135 | 1430065 | Chip resistor | 10 k | 5 % 0.063 | W 0603 |
| R136 | 1430087 | Chip resistor | 100 k | 5 % 0.063 | W 0603 |
| R137 | 1430087 | Chip resistor | 100 k | 5 % 0.063 | W 0603 |
| R138 | | Chip resistor | 220 | 5 % 0.063 | W 0603 |
| R141 | 1430043 | Chip resistor | 2.2 k | 5 % 0.063 | W 0603 |
| R142 | 1430043 | Chip resistor | 2.2 k | 5 % 0.063 | W 0603 |
| R143 | | Chip resistor | 100 k | 5 % 0.063 | W 0603 |
| R146 | | Chip resistor | 22 | 5 % 0.063 | W 0603 |
| R147 | | Chip resistor | 22 | 5 % 0.063 | W 0603 |
| R148 | 1430055 | Chip resistor | 6.8 k | 5 % 0.063 | W 0603 |
| R149 | | Chip resistor | 10 k | 5 % 0.063 | |
| R156 | 1430051 | • | 4.7 k | 5 % 0.063 | W 0603 |
| R157 | 1430051 | Chip resistor | 4.7 k | 5 % 0.063 | W 0603 |
| R163 | 1430031 | Chip resistor | 100 k | 1 % 0.063 | |
| R164 | 1430031 | Chip resistor | 100 k | 1 % 0.063 | |
| R165 | 1430031 | • | 100 k | 1 % 0.063 | |
| R168 | | Chip resistor | 10 k | 5 % 0.063 | |
| R169 | | Chip resistor | 220 k | 2 % 0.063 | |
| R170 | | Chip resistor | 10 k | 5 % 0.063 | |
| | | | | | |

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|---------|-----------|---------------|-------|------------------|---------------|
| R171 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R172 | | Chip resistor | 22 k | 5 % 0.063 W 0603 | |
| R182 | | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R183 | | Chip resistor | 100 k | 1 % 0.063 W 0603 | |
| R184 | | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R185 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R186 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R201 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R202 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R203 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R204 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R205 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R206 | | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R207 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 | |
| R208 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 | |
| R209 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 | |
| R210 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 | |
| R211 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R212 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R213 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R214 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R215 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R216 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R217 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R219 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R221 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R222 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R223 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R224 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R225 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R226 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R227 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R228 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R250 | 1430043 | Chip resistor | 2.2 k | 5 % 0.063 W 0603 | |
| R251 | 1430099 | Chip resistor | 330 k | 5 % 0.063 W 0603 | |
| R252 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R253 | 1430031 | Chip resistor | 100 k | 1 % 0.063 W 0603 | |
| R254 | 1430294 | Chip resistor | 220 k | 2 % 0.063 W 0603 | |
| R256 | 1430071 | Chip resistor | 22 k | 5 % 0.063 W 0603 | |
| R257 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R260 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 | |
| R261 | 1430095 | Chip resistor | 220 k | 5 % 0.063 W 0603 | |

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| R262 | 1430085 | Chip resistor | 82 k | 5 % 0.063 W 0603 |
|------|---------|---------------|-------|------------------|
| R263 | 1430095 | Chip resistor | 220 k | 5 % 0.063 W 0603 |
| R264 | 1430079 | Chip resistor | 47 k | 5 % 0.063 W 0603 |
| R265 | 1430079 | Chip resistor | 47 k | 5 % 0.063 W 0603 |
| R266 | 1430075 | Chip resistor | 33 k | 5 % 0.063 W 0603 |
| R267 | 1430079 | Chip resistor | 47 k | 5 % 0.063 W 0603 |
| R268 | 1430111 | Chip resistor | 1.0 M | 5 % 0.063 W 0603 |
| R269 | 1430111 | Chip resistor | 1.0 M | 5 % 0.063 W 0603 |
| R270 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R271 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R272 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R273 | 1430071 | Chip resistor | 22 k | 5 % 0.063 W 0603 |
| R274 | 1430075 | Chip resistor | 33 k | 5 % 0.063 W 0603 |
| R275 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R300 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R301 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R302 | 1430053 | Chip resistor | 5.6 k | 5 % 0.063 W 0603 |
| R311 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R313 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R331 | 1430001 | Chip resistor | 100 | 5 % 0.063 W 0603 |
| R332 | 1430001 | Chip resistor | 100 | 5 % 0.063 W 0603 |
| R344 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R346 | 1430045 | Chip resistor | 2.7 k | 5 % 0.063 W 0603 |
| R361 | 1430167 | Chip resistor | 47 | 5 % 0.063 W 0603 |
| R362 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R392 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R400 | 1430013 | Chip resistor | 330 | 5 % 0.063 W 0603 |
| R403 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R407 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R408 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R409 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R410 | 1430073 | Chip resistor | 27 k | 5 % 0.063 W 0603 |
| R411 | 1430051 | Chip resistor | 4.7 k | 5 % 0.063 W 0603 |
| R420 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R421 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R436 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R437 | 1430167 | Chip resistor | 47 | 5 % 0.063 W 0603 |
| R439 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R440 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R441 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 |
| R442 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R444 | 1430015 | Chip resistor | 470 | 5 % 0.063 W 0603 |

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|----------|-----------|---------------|-------|------------------|---------------|
| R445 | 1430015 | Chip resistor | 470 | 5 % 0.063 W 0603 | |
| R446 | | Chip resistor | 470 | 5 % 0.063 W 0603 | |
| R447 | | Chip resistor | 470 | | |
| R448 | | Chip resistor | 10 k | | |
| R449 | | Chip resistor | 10 k | | |
| R451 | | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R452 | | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R453 | | Chip resistor | 680 | 5 % 0.063 W 0603 | |
| R454 | | Chip resistor | 680 | 5 % 0.063 W 0603 | |
| R455 | | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R456 | | Chip resistor | 47 k | 5 % 0.063 W 0603 | |
| R457 | 1800659 | NTC resistor | 47 k | 10 % 0.12 W 0805 | |
| R460 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R461 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 | |
| R501 | 1430151 | Chip resistor | 10 | 5 % 0.063 W 0603 | |
| R502 | 1430047 | Chip resistor | 3.3 k | 5 % 0.063 W 0603 | |
| R503 | 1430047 | Chip resistor | 3.3 k | 5 % 0.063 W 0603 | |
| R504 | 1430171 | Chip resistor | 68 | 5 % 0.063 W 0603 | |
| R505 | 1430055 | Chip resistor | 6.8 k | 5 % 0.063 W 0603 | |
| R506 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R507 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R508 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R511 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R512 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R513 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R514 | 1430087 | Chip resistor | 100 k | 5 % 0.063 W 0603 | |
| R515 | 1430055 | Chip resistor | 6.8 k | 5 % 0.063 W 0603 | |
| R518 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R519 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R520 | 1430001 | Chip resistor | 100 | 5 % 0.063 W 0603 | |
| R523 | 1430009 | Chip resistor | 220 | 5 % 0.063 W 0603 | |
| R524 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R525 | 1430009 | Chip resistor | 220 | 5 % 0.063 W 0603 | |
| R526 | 1430051 | Chip resistor | 4.7 k | 5 % 0.063 W 0603 | |
| R527 | 1430045 | Chip resistor | 2.7 k | 5 % 0.063 W 0603 | |
| R528 | 1430013 | Chip resistor | 330 | 5 % 0.063 W 0603 | |
| R529 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R541 | 1430159 | Chip resistor | 22 | 5 % 0.063 W 0603 | |
| R542 | 1430009 | Chip resistor | 220 | 5 % 0.063 W 0603 | |
| R543 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 | |
| R544 | 1430039 | Chip resistor | 1.5 k | 5 % 0.063 W 0603 | |
| R545 | 1430045 | Chip resistor | 2.7 k | 5 % 0.063 W 0603 | |

| System | Module | | | Technical Documentation |
|--------|---------|---------------|-------|--------------------------|
| Cyclom | Modulo | | | reclinical Documentation |
| R546 | 1430167 | Chip resistor | 47 | 5 % 0.063 W 0603 |
| R547 | 1430015 | Chip resistor | 470 | 5 % 0.063 W 0603 |
| R548 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R551 | 1430053 | Chip resistor | 5.6 k | 5 % 0.063 W 0603 |
| R552 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R553 | 1430053 | Chip resistor | 5.6 k | 5 % 0.063 W 0603 |
| R554 | 1430053 | Chip resistor | 5.6 k | 5 % 0.063 W 0603 |
| R555 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R556 | 1430053 | Chip resistor | 5.6 k | 5 % 0.063 W 0603 |
| R557 | 1430007 | Chip resistor | 180 | 5 % 0.063 W 0603 |
| R558 | | Chip resistor | 180 | 5 % 0.063 W 0603 |
| R559 | 1430013 | Chip resistor | 330 | 5 % 0.063 W 0603 |
| R560 | 1430047 | Chip resistor | 3.3 k | 5 % 0.063 W 0603 |
| R561 | | Chip resistor | 47 k | 5 % 0.063 W 0603 |
| R562 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R563 | 1430009 | Chip resistor | 220 | 5 % 0.063 W 0603 |
| R566 | | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R568 | | Chip resistor | 220 | 5 % 0.063 W 0603 |
| R570 | 1430001 | Chip resistor | 100 | 5 % 0.063 W 0603 |
| R571 | | Chip resistor | 2.2 k | 5 % 0.063 W 0603 |
| R572 | | Chip resistor | 47 k | 5 % 0.063 W 0603 |
| R573 | 1430065 | Chip resistor | 10 k | 5 % 0.063 W 0603 |
| R574 | 1430071 | Chip resistor | 22 k | 5 % 0.063 W 0603 |
| R576 | 1430035 | Chip resistor | 1.0 k | 5 % 0.063 W 0603 |
| R578 | 1430077 | Chip resistor | 39 k | 5 % 0.063 W 0603 |
| R579 | | Chip resistor | | 5 % 0.063 W 0603 |
| R580 | 1430073 | Chip resistor | 27 k | 5 % 0.063 W 0603 |
| R601 | 1430043 | Chip resistor | 2.2 k | 5 % 0.063 W 0603 |
| R602 | | Chip resistor | 2.2 k | 5 % 0.063 W 0603 |
| R603 | | Chip resistor | 2.2 k | 5 % 0.063 W 0603 |
| R701 | | Chip resistor | 4.7 k | 5 % 0.063 W 0603 |
| R702 | | Chip resistor | 82 | 5 % 0.063 W 0603 |
| R703 | | Chip resistor | 2.7 k | 5 % 0.063 W 0603 |
| R704 | | Chip resistor | 22 | 5 % 0.063 W 0603 |
| R705 | | Chip resistor | 330 | 5 % 0.063 W 0603 |
| R717 | | Chip resistor | 470 | 5 % 0.063 W 0603 |
| R721 | | Chip resistor | 10 | 5 % 0.063 W 0603 |
| R722 | | Chip resistor | 470 | 5 % 0.063 W 0603 |
| R723 | | Chip resistor | 2.7 k | 5 % 0.063 W 0603 |
| R725 | | Chip resistor | 1.5 k | 5 % 0.063 W 0603 |
| R731 | | Chip resistor | 27 k | 5 % 0.063 W 0603 |
| R732 | 1430001 | Chip resistor | 100 | 5 % 0.063 W 0603 |

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| R733 1430075 Chip resistor 33 k 5 % 0.063 W 0603 R734 1430051 Chip resistor 4.7 k 5 % 0.063 W 0603 | |
|---|--|
| ' | |
| · · | |
| R736 1430159 Chip resistor 22 5 % 0.063 W 0603 | |
| R737 1430009 Chip resistor 220 5 % 0.063 W 0603 | |
| R738 1430009 Chip resistor 220 5 % 0.063 W 0603 | |
| R739 1430009 Chip resistor 220 5 % 0.063 W 0603 | |
| R746 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 | |
| R748 1430009 Chip resistor 220 5 % 0.063 W 0603 | |
| R751 1412279 Chip resistor 2.2 5 % 0.1 W 0805 | |
| R752 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 | |
| R761 1430021 Chip resistor 680 5 % 0.063 W 0603 | |
| R762 1430007 Chip resistor 180 5 % 0.063 W 0603 | |
| R763 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 | |
| R764 1430023 Chip resistor 820 5 % 0.063 W 0603 | |
| R765 1430142 Chip resistor 4.7 5 % 0.063 W 0603 | |
| R773 1430019 Chip resistor 560 5 % 0.063 W 0603 | |
| R774 1430087 Chip resistor 100 k 5 % 0.063 W 0603 | |
| R776 1430063 Chip resistor 12 k 5 % 0.063 W 0603 | |
| R777 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 | |
| R779 1430151 Chip resistor 10 5 % 0.063 W 0603 | |
| R780 1430065 Chip resistor 10 k 5 % 0.063 W 0603 | |
| R781 1430043 Chip resistor 2.2 k 5 % 0.063 W 0603 | |
| R783 1430043 Chip resistor 2.2 k 5 % 0.063 W 0603 | |
| R784 1430167 Chip resistor 47 5 % 0.063 W 0603 | |
| R785 1430013 Chip resistor 330 5 % 0.063 W 0603 | |
| R786 1430041 Chip resistor 1.8 k 5 % 0.063 W 0603 | |
| R793 1430069 Chip resistor 18 k 5 % 0.063 W 0603 | |
| R800 1430065 Chip resistor 10 k 5 % 0.063 W 0603 | |
| R801 1430079 Chip resistor 47 k 5 % 0.063 W 0603 | |
| R802 1430079 Chip resistor 47 k 5 % 0.063 W 0603 | |
| R803 1430001 Chip resistor 100 5 % 0.063 W 0603 | |
| R804 1430069 Chip resistor 18 k 5 % 0.063 W 0603 | |
| R805 1430069 Chip resistor 18 k 5 % 0.063 W 0603 | |
| R806 1430065 Chip resistor 10 k 5 % 0.063 W 0603 | |
| R807 1430041 Chip resistor 1.8 k 5 % 0.063 W 0603 | |
| R808 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 | |
| R811 1430051 Chip resistor 4.7 k 5 % 0.063 W 0603 | |
| R812 1430051 Chip resistor 4.7 k 5 % 0.063 W 0603 | |
| R813 1430051 Chip resistor 4.7 k 5 % 0.063 W 0603 | |
| R814 1430043 Chip resistor 2.2 k 5 % 0.063 W 0603 | |
| R815 1430043 Chip resistor 2.2 k 5 % 0.063 W 0603 | |
| R816 1430081 Chip resistor 56 k 5 % 0.063 W 0603 | |

System Module **Technical Documentation** R817 1430165 Chip resistor 39 5 % 0.063 W 0603 R818 1430035 Chip resistor 1.0 k 5 % 0.063 W 0603 1430001 Chip resistor 100 5 % 0.063 W 0603 R819 R821 1430069 Chip resistor 18 k 5 % 0.063 W 0603 R822 1430055 Chip resistor 6.8 k 5 % 0.063 W 0603 R823 1430167 Chip resistor 47 5 % 0.063 W 0603 R824 1430001 Chip resistor 100 5 % 0.063 W 0603 R826 1430063 Chip resistor 12 k 5 % 0.063 W 0603 R840 1430051 Chip resistor 4.7 k 5 % 0.063 W 0603 4.7 k R841 1430051 Chip resistor 5 % 0.063 W 0603 R842 1430049 Chip resistor 3.9 k 5 % 0.063 W 0603 R843 1430045 Chip resistor 2.7 k 5 % 0.063 W 0603 R844 1430009 Chip resistor 220 5 % 0.063 W 0603 R845 1430151 Chip resistor 10 5 % 0.063 W 0603 1430001 Chip resistor 100 R846 5 % 0.063 W 0603 47 R847 1430167 Chip resistor 5 % 0.063 W 0603 470 R863 1430015 Chip resistor 5 % 0.063 W 0603 C103 2310017 Ceramic cap. 22 n 10 % 100 V 0805 C104 22 n 2310017 Ceramic cap. 10 % 100 V 0805 C107 2310017 Ceramic cap. 22 n 10 % 100 V 0805 2310017 Ceramic cap. C108 22 n 10 % 100 V 0805 C110 1.0 n 2320083 Ceramic cap. 5 % 50 V 0603 C111 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C112 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C113 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C121 2320045 Ceramic cap. 27 p 5 % 50 V 0603 5 % 50 V 0603 C122 2320045 Ceramic cap. 27 p C123 5 % 50 V 0603 2320045 Ceramic cap. 27 p C124 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C125 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C126 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C127 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C128 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C129 2310791 Ceramic cap. 33 n 20 % 50 V 0805 C130 2310791 Ceramic cap. 33 n 20 % 50 V 0805 C131 2611668 Tantalum cap. 4.7 u 20 % 10 V 3.2x1.6x1.6 C132 2312410 Ceramic cap. 1.0 u 10 % 16 V 1206 C133 2320107 Ceramic cap. 10 n 5 % 50 V 0603 C134 2320107 Ceramic cap. 10 n 5 % 50 V 0603 C135 2320107 Ceramic cap. 10 n 5 % 50 V 0603 C136 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603

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10 n

5 % 50 V 0603

C137

2320107 Ceramic cap.

| Technica | al Docume | ntation | | | System Module |
|----------|-----------|----------------|-------|-----------------------|---------------|
| C138 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C139 | | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C140 | | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C141 | | Ceramic cap. | 47 n | 20 % 25 V 0805 | |
| C142 | | Tantalum cap. | 100 u | 20 % 10 V 7.3x4.3x2.9 | |
| C144 | | Ceramic cap. | 2.2 n | 10 % 100 V 0805 | |
| C145 | | Electrol. cap. | 47 u | 20 % 100 V 10x10x10.5 | 5 |
| C147 | | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C151 | | Ceramic cap. | 47 n | 20 % 25 V 0805 | |
| C152 | | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C153 | | Ceramic cap. | 100 n | 10 % 25 V 0805 | |
| C154 | | Ceramic cap. | 100 n | 10 % 25 V 0805 | |
| C181 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C190 | | Electrol. cap. | 47 u | 20 % 100 V 10x10x10. | 5 |
| C231 | 2310007 | Ceramic cap. | 18 n | 10 % 100 V 1206 | |
| C232 | | Ceramic cap. | 18 n | 10 % 100 V 1206 | |
| C240 | 2310013 | Ceramic cap. | 100 n | 10 % 100 V 1210 | |
| C251 | 2307816 | Ceramic cap. | 47 n | 20 % 25 V 0805 | |
| C252 | 2307816 | Ceramic cap. | 47 n | 20 % 25 V 0805 | |
| C253 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 | |
| C255 | 2310007 | Ceramic cap. | 18 n | 10 % 100 V 1206 | |
| C256 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 | |
| C260 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 | |
| C261 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 | |
| C270 | 2320067 | Ceramic cap. | 220 p | 5 % 50 V 0603 | |
| C271 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 | |
| C272 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 | |
| C273 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 | |
| C300 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C301 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C302 | 2604431 | Tantalum cap. | 10 u | 20 % 16 V 6.0x3.2x2.5 | |
| C303 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C311 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C312 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C313 | 2610153 | Tantalum cap. | 10 u | 20 % 6.0x3.2x2.5 | |
| C314 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C315 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C316 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |
| C317 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 | |
| C318 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C319 | 2610153 | Tantalum cap. | 10 u | 20 % 6.0x3.2x2.5 | |
| C320 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 | |

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| C321 | | Tantalum cap. | 10 u | 20 % 6.0x3.2x2.5 |
|------|---------|---------------|-------|------------------|
| C322 | | Ceramic cap. | 10 n | 5 % 50 V 0603 |
| C331 | | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C332 | | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C333 | | Ceramic cap. | 10 n | 5 % 50 V 0603 |
| C334 | 2320043 | Ceramic cap. | 22 p | 5 % 50 V 0603 |
| C335 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C336 | 2320043 | Ceramic cap. | 22 p | 5 % 50 V 0603 |
| C351 | 2610153 | Tantalum cap. | 10 u | 20 % 6.0x3.2x2.5 |
| C352 | 2320107 | Ceramic cap. | 10 n | 5 % 50 V 0603 |
| C353 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C360 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C361 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C365 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C366 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C400 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C401 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C403 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 |
| C404 | 2320053 | Ceramic cap. | 56 p | 5 % 50 V 0603 |
| C405 | 2320035 | Ceramic cap. | 10 p | 5 % 50 V 0603 |
| C406 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C407 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C408 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C409 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C410 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C420 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C421 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C430 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C431 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C432 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C433 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C440 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C441 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C442 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C445 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C451 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C452 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C453 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C454 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C455 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C456 | 2320110 | Ceramic cap. | 10 n | 10 % 50 V 0603 |
| C457 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| | | | | |

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System Module **Technical Documentation** C458 2320110 Ceramic cap. 10 n 10 % 50 V 0603 C459 2312410 Ceramic cap. 1.0 u 10 % 16 V 1206 C460 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C461 2312410 Ceramic cap. 1.0 u 10 % 16 V 1206 C462 2320110 Ceramic cap. 10 n 10 % 50 V 0603 1.0 p C501 2320011 Ceramic cap. 0.25 % 50 V 0603 C502 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C503 2320043 Ceramic cap. 22 p 5 % 50 V 0603 C504 2320087 Ceramic cap. 1.5 n 5 % 50 V 0603 C505 2320011 Ceramic cap. 1.0 p 0.25 % 50 V 0603 C506 2320043 Ceramic cap. 22 p 5 % 50 V 0603 C508 2320087 Ceramic cap. 1.5 n 5 % 50 V 0603 C509 2320043 Ceramic cap. 22 p 5 % 50 V 0603 C511 2320051 Ceramic cap. 47 p 5 % 50 V 0603 C512 2320023 Ceramic cap. 0.25 % 50 V 0603 3.3 pC513 2320023 Ceramic cap. 3.3 p0.25 % 50 V 0603 C514 2320039 Ceramic cap. 15 p 5 % 50 V 0603 C515 2320043 Ceramic cap. 22 p 5 % 50 V 0603 C516 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C517 2320049 Ceramic cap. 39 p 5 % 50 V 0603 C518 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C519 100 p 5 % 50 V 0603 2320059 Ceramic cap. C520 2320043 Ceramic cap. 22 p 5 % 50 V 0603 C521 2320019 Ceramic cap. 0.25 % 50 V 0603 2.2 p C522 2320053 Ceramic cap. 56 p 5 % 50 V 0603 C530 0.25 % 50 V 0603 2320015 Ceramic cap. 1.5 p C531 2320017 Ceramic cap. 1.8 p 0.25 % 50 V 0603 C532 2320017 Ceramic cap. 1.8 p 0.25 % 50 V 0603 C539 2320053 Ceramic cap. 56 p 5 % 50 V 0603 C541 5 % 50 V 0603 2320095 Ceramic cap. 3.3 n C542 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C543 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C544 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C545 2320067 Ceramic cap. 220 p 5 % 50 V 0603 C546 2320067 Ceramic cap. 220 p 5 % 50 V 0603 5 % 50 V 0603 C551 2320035 Ceramic cap. 10 p C552 2320059 Ceramic cap. 100 p 5 % 50 V 0603

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100 p

180 p

180 p

2.2 n

100 p

5 % 50 V 0603

5 % 50 V 0603

5 % 50 V 0603

5 % 50 V 0603 5 % 50 V 0603

C553

C554

C555

C556

C557

2320059 Ceramic cap.

2320464 Ceramic cap.

2320464 Ceramic cap.

2320091 Ceramic cap.

2320059 Ceramic cap.

Technical Documentation

| C558 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
|------|---------|--------------|-------|------------------|
| C559 | 2320091 | Ceramic cap. | 2.2 n | 5 % 50 V 0603 |
| C560 | 2320091 | Ceramic cap. | 2.2 n | 5 % 50 V 0603 |
| C561 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C562 | 2320075 | Ceramic cap. | 470 p | 5 % 50 V 0603 |
| C563 | 2320051 | Ceramic cap. | 47 p | 5 % 50 V 0603 |
| C566 | 2320051 | Ceramic cap. | 47 p | 5 % 50 V 0603 |
| C569 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 |
| C570 | 2320131 | Ceramic cap. | 33 n | 10 % 16 V 0603 |
| C571 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 |
| C572 | 2310791 | Ceramic cap. | 33 n | 20 % 50 V 0805 |
| C573 | 2320053 | Ceramic cap. | 56 p | 5 % 50 V 0603 |
| C574 | 2320053 | Ceramic cap. | 56 p | 5 % 50 V 0603 |
| C575 | 2320029 | Ceramic cap. | 5.6 p | 0.25 % 50 V 0603 |
| C580 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 |
| C600 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C601 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C602 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C603 | 2312410 | Ceramic cap. | 1.0 u | 10 % 16 V 1206 |
| C604 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C606 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C607 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C608 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C609 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C610 | 2310784 | Ceramic cap. | 100 n | 10 % 25 V 0805 |
| C701 | 2320047 | Ceramic cap. | 33 p | 5 % 50 V 0603 |
| C702 | 2320023 | Ceramic cap. | 3.3 p | 0.25 % 50 V 0603 |
| C703 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 |
| C704 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C705 | 2320019 | Ceramic cap. | 2.2 p | 0.25 % 50 V 0603 |
| C710 | 2320031 | Ceramic cap. | 6.8 p | 0.25 % 50 V 0603 |
| C711 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 |
| C712 | 2320029 | Ceramic cap. | 5.6 p | 0.25 % 50 V 0603 |
| C713 | 2320023 | Ceramic cap. | 3.3 p | 0.25 % 50 V 0603 |
| C714 | 2320039 | Ceramic cap. | 15 p | 5 % 50 V 0603 |
| C715 | 2320023 | Ceramic cap. | 3.3 p | 0.25 % 50 V 0603 |
| C716 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 |
| C721 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 |
| C722 | 2320011 | Ceramic cap. | 1.0 p | 0.25 % 50 V 0603 |
| C724 | 2320021 | Ceramic cap. | 2.7 p | 0.25 % 50 V 0603 |
| C725 | 2320035 | Ceramic cap. | 10 p | 5 % 50 V 0603 |
| C726 | 2320011 | Ceramic cap. | 1.0 p | 0.25 % 50 V 0603 |

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| Technic | cal Docume | ntation | | | System Module |
|---------|------------|----------------|--------|-----------------------|---------------|
| C731 | 2320051 | Ceramic cap. | 47 p | 5 % 50 V 0603 | |
| C733 | 2320019 | Ceramic cap. | 2.2 p | 0.25 % 50 V 0603 | |
| C735 | | Ceramic cap. | 4.7 p | | |
| C736 | | Ceramic cap. | 1.5 p | 0.25 % 50 V 0603 | |
| C737 | 2320029 | Ceramic cap. | 5.6 p | 0.25 % 50 V 0603 | |
| C738 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 | |
| C739 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 | |
| C740 | 2320055 | Ceramic cap. | 68 p | 5 % 50 V 0603 | |
| C742 | 2320023 | Ceramic cap. | 3.3 p | 0.25 % 50 V 0603 | |
| C743 | 2320025 | Ceramic cap. | 3.9 p | 0.25 % 50 V 0603 | |
| C744 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C745 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 | |
| C746 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 | |
| C752 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C753 | 2320055 | Ceramic cap. | 68 p | 5 % 50 V 0603 | |
| C754 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 | |
| C755 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C756 | 2320033 | Ceramic cap. | 8.2 p | 0.25 % 50 V 0603 | |
| C757 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C758 | 2320041 | Ceramic cap. | 18 p | 5 % 50 V 0603 | |
| C760 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C761 | 2320077 | Ceramic cap. | 560 p | 5 % 50 V 0603 | |
| C762 | 2320055 | Ceramic cap. | 68 p | 5 % 50 V 0603 | |
| C763 | 2320011 | Ceramic cap. | 1.0 p | 0.25 % 50 V 0603 | |
| C764 | 2320055 | Ceramic cap. | 68 p | 5 % 50 V 0603 | |
| C766 | 2320035 | Ceramic cap. | 10 p | 5 % 50 V 0603 | |
| C767 | 2320021 | Ceramic cap. | 2.7 p | 0.25 % 50 V 0603 | |
| C768 | 2320077 | Ceramic cap. | 560 p | 5 % 50 V 0603 | |
| C770 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 | |
| C771 | 2500708 | Electrol. cap. | 3300 u | 20 % 16 V | |
| C780 | 2320041 | Ceramic cap. | 18 p | 5 % 50 V 0603 | |
| C781 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 | |
| C782 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 | |
| C783 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 | |
| C784 | 2320035 | Ceramic cap. | 10 p | 5 % 50 V 0603 | |
| C785 | 2320035 | Ceramic cap. | 10 p | 5 % 50 V 0603 | |
| C800 | 2604079 | Tantalum cap. | 0.22 u | 20 % 35 V 3.2x1.6x1.6 | 5 |
| C801 | 2320131 | Ceramic cap. | 33 n | 10 % 16 V 0603 | |
| C802 | 2320029 | Ceramic cap. | 5.6 p | 0.25 % 50 V 0603 | |
| C803 | 2320067 | Ceramic cap. | 220 p | 5 % 50 V 0603 | |
| C804 | | Ceramic cap. | 56 p | | |
| C805 | 2320067 | Ceramic cap. | 220 p | 5 % 50 V 0603 | |
| | | | | | |

TFE-2 PAMS

| C806 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C807 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C809 2320027 Ceramic cap. 1.0 n 5 % 50 V 0603 C814 2320027 Ceramic cap. 1.0 n 2 % 50 V 1206 C815 2313104 Ceramic cap. 100 p 5 % 50 V 0603 C817 2320059 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C818 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C821 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C826 2320095 Ceramic cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 4.7 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 | System Module | | | | Technical Documentation |
|--|---------------|---------|---------------|-----------|-------------------------|
| C807 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C809 2320028 Ceramic cap. 1.0 n 5 % 50 V 0603 C814 2320027 Ceramic cap. 1.0 n 2 % 50 V 1206 C815 2313104 Ceramic cap. 1.0 n 2 % 50 V 1206 C817 2320059 Ceramic cap. 5 % 50 V 0603 C818 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 10603 C829 2320059 Ceramic cap. 100 p 5 % 50 V 10603 C829 2320047 Ceramic cap. 100 p 5 % 50 V 10603 C841 2610100 Tantalum cap. <t< td=""><td>C806</td><td>2610100</td><td>Tantalum cap.</td><td>1 u</td><td>20 % 10 V 2.0x1.3x1.2</td></t<> | C806 | 2610100 | Tantalum cap. | 1 u | 20 % 10 V 2.0x1.3x1.2 |
| C809 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C814 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 10603 C815 2313104 Ceramic cap. 100 p 5 % 50 V 10603 C817 2320053 Ceramic cap. 56 p 5 % 50 V 0603 C818 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C819 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 4.7 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C829 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 1 u 20 % 10 V 2.0x1.3x1.2 C841 231040 Tant | C807 | | • | 3.3 n | 5 % 50 V 0603 |
| C815 2313104 Ceramic cap. 1.0 n 2 % 50 V 1206 C817 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C818 2320050 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 4.7 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 4.7 n 5 % 50 V 0603 C829 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C829 2320047 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 27 p 5 % 50 V 0603 C843 2320045 Ceramic cap. 12 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. | C809 | | • | | 5 % 50 V 0603 |
| C817 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C818 2320053 Ceramic cap. 56 p 5 % 50 V 0603 C819 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320047 Ceramic cap. 1 u 20 % 10 V 2.0x1.3x1.2 C844 2320037 Ceramic cap. 1 p 5 % 50 V 0603 C844 2320041 | C814 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 |
| C817 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C818 2320053 Ceramic cap. 56 p 5 % 50 V 0603 C819 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320047 Ceramic cap. 1 u 20 % 10 V 2.0x1.3x1.2 C844 2320037 Ceramic cap. 1 p 5 % 50 V 0603 C844 2320041 | C815 | | • | 1.0 n | 2 % 50 V 1206 |
| C819 2320019 Ceramic cap. 2.2 p 0.25 % 50 V 0603 C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 4.7 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 100 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C847 2320027 Ceramic cap. 1.0 n 5 % 50 V 0603 C849 2320049 Ceram | C817 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C823 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 27 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320040 Ceramic cap. 100 p 5 % 50 V 0603 C850 2320041 Cerami | C818 | 2320053 | Ceramic cap. | 56 p | 5 % 50 V 0603 |
| C824 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 4.7 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 100 p 5 % 50 V 0603 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C849 2320083 Ceramic cap. 10 p 5 % 50 V 0603 C850 2320049 Ceramic cap | C819 | 2320019 | Ceramic cap. | 2.2 p | 0.25 % 50 V 0603 |
| C825 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 4.7 n 5 % 50 V 1206 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 18 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 10 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. <td>C823</td> <td>2610100</td> <td>Tantalum cap.</td> <td>1 u</td> <td>20 % 10 V 2.0x1.3x1.2</td> | C823 | 2610100 | Tantalum cap. | 1 u | 20 % 10 V 2.0x1.3x1.2 |
| C826 2320095 Ceramic cap. 3.3 n 5 % 50 V 0603 C827 2310248 Ceramic cap. 4.7 n 5 % 50 V 1206 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C829 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C849 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C850 2320041 Ceramic cap. 1.0 n 5 % 50 V 0603 C851 2320049 Ceramic cap. 1.0 n 5 % 50 V 0603 C856 2320059 Ceramic cap. | C824 | | • | 3.3 n | 5 % 50 V 0603 |
| C827 2310248 Ceramic cap. 4.7 n 5 % 50 V 1206 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C829 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 100 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 10 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 10 p 5 % 50 V 0603 C856 2320059 Ceramic cap. | C825 | 2610100 | Tantalum cap. | 1 u | 20 % 10 V 2.0x1.3x1.2 |
| C827 2310248 Ceramic cap. 4.7 n 5 % 50 V 1206 C828 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C829 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 100 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 10 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 10 p 5 % 50 V 0603 C856 2320059 Ceramic cap. | C826 | 2320095 | Ceramic cap. | 3.3 n | 5 % 50 V 0603 |
| C829 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 18 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 8.2 p 0.25 % 50 V 0603 C846 2320037 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 19 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r | C827 | | | 4.7 n | 5 % 50 V 1206 |
| C840 2320047 Ceramic cap. 33 p 5 % 50 V 0603 C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320037 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320081 Ceramic cap. 18 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/10 | C828 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C841 2610100 Tantalum cap. 1 u 20 % 10 V 2.0x1.3x1.2 C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C848 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 18 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 <td>C829</td> <td>2320059</td> <td>Ceramic cap.</td> <td>100 p</td> <td>5 % 50 V 0603</td> | C829 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C843 2320045 Ceramic cap. 27 p 5 % 50 V 0603 C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 100 p 5 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 18 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter Z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter Z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter Z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter Z>600r/100m 0r6max 0.2a 0805 | C840 | 2320047 | Ceramic cap. | 33 p | 5 % 50 V 0603 |
| C844 2320037 Ceramic cap. 12 p 5 % 50 V 0603 C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 8.2 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 < | C841 | 2610100 | Tantalum cap. | 1 u | 20 % 10 V 2.0x1.3x1.2 |
| C845 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C846 2320033 Ceramic cap. 8.2 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 18 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 <td< td=""><td>C843</td><td>2320045</td><td>Ceramic cap.</td><td>27 p</td><td>5 % 50 V 0603</td></td<> | C843 | 2320045 | Ceramic cap. | 27 p | 5 % 50 V 0603 |
| C846 2320033 Ceramic cap. 8.2 p 0.25 % 50 V 0603 C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 18 p 5 % 50 V 0603 C850 2320041 Ceramic cap. 39 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 | C844 | 2320037 | Ceramic cap. | 12 p | 5 % 50 V 0603 |
| C847 2320027 Ceramic cap. 4.7 p 0.25 % 50 V 0603 C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 366946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 | C845 | 2320041 | Ceramic cap. | 18 p | 5 % 50 V 0603 |
| C848 2320059 Ceramic cap. 100 p 5 % 50 V 0603 C849 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 39 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 <td< td=""><td>C846</td><td>2320033</td><td>Ceramic cap.</td><td>8.2 p</td><td>0.25 % 50 V 0603</td></td<> | C846 | 2320033 | Ceramic cap. | 8.2 p | 0.25 % 50 V 0603 |
| C849 2320083 Ceramic cap. 1.0 n 5 % 50 V 0603 C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 100 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filt | C847 | 2320027 | Ceramic cap. | 4.7 p | 0.25 % 50 V 0603 |
| C850 2320041 Ceramic cap. 18 p 5 % 50 V 0603 C851 2320049 Ceramic cap. 39 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600 | C848 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| C851 2320049 Ceramic cap. 39 p 5 % 50 V 0603 C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | C849 | 2320083 | Ceramic cap. | 1.0 n | 5 % 50 V 0603 |
| C856 2320059 Ceramic cap. 100 p 5 % 50 V 0603 L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | C850 | 2320041 | Ceramic cap. | 18 p | 5 % 50 V 0603 |
| L101 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | C851 | 2320049 | Ceramic cap. | 39 p | 5 % 50 V 0603 |
| L102 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L104 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | C856 | 2320059 | Ceramic cap. | 100 p | 5 % 50 V 0603 |
| L103 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L104 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L130 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L131 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L141 3607551 Coil 125 u 10 % 2 A 16x12 L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L101 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L1043640011Filterz>600r/100m 0r6max 0.2a 0805L1303640011Filterz>600r/100m 0r6max 0.2a 0805L1313640011Filterz>600r/100m 0r6max 0.2a 0805L1413607551Coil125 u 10 % 2 A 16x12L3013606946Ferrite bead0.2r 26r/100mhz 1206L3023606946Ferrite bead0.2r 26r/100mhz 1206L3033640011Filterz>600r/100m 0r6max 0.2a 0805L3603640011Filterz>600r/100m 0r6max 0.2a 0805L4013640011Filterz>600r/100m 0r6max 0.2a 0805L4313640011Filterz>600r/100m 0r6max 0.2a 0805 | L102 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L1303640011Filterz>600r/100m 0r6max 0.2a 0805L1313640011Filterz>600r/100m 0r6max 0.2a 0805L1413607551Coil125 u 10 % 2 A 16x12L3013606946Ferrite bead0.2r 26r/100mhz 1206L3023606946Ferrite bead0.2r 26r/100mhz 1206L3033640011Filterz>600r/100m 0r6max 0.2a 0805L3603640011Filterz>600r/100m 0r6max 0.2a 0805L4003640011Filterz>600r/100m 0r6max 0.2a 0805L4013640011Filterz>600r/100m 0r6max 0.2a 0805L4313640011Filterz>600r/100m 0r6max 0.2a 0805 | L103 | 3640011 | Filter | z>600r/ | 100m 0r6max 0.2a 0805 |
| L1313640011Filterz>600r/100m 0r6max 0.2a 0805L1413607551Coil125 u 10 % 2 A 16x12L3013606946Ferrite bead0.2r 26r/100mhz 1206L3023606946Ferrite bead0.2r 26r/100mhz 1206L3033640011Filterz>600r/100m 0r6max 0.2a 0805L3603640011Filterz>600r/100m 0r6max 0.2a 0805L4003640011Filterz>600r/100m 0r6max 0.2a 0805L4013640011Filterz>600r/100m 0r6max 0.2a 0805L4313640011Filterz>600r/100m 0r6max 0.2a 0805 | L104 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L1413607551Coil125 u10 % 2 A 16x12L3013606946Ferrite bead0.2r 26r/100mhz 1206L3023606946Ferrite bead0.2r 26r/100mhz 1206L3033640011Filterz>600r/100m 0r6max 0.2a 0805L3603640011Filterz>600r/100m 0r6max 0.2a 0805L4003640011Filterz>600r/100m 0r6max 0.2a 0805L4013640011Filterz>600r/100m 0r6max 0.2a 0805L4313640011Filterz>600r/100m 0r6max 0.2a 0805 | L130 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L301 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L131 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L302 3606946 Ferrite bead 0.2r 26r/100mhz 1206 L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L141 | 3607551 | Coil | 125 u | 10 % 2 A 16x12 |
| L303 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L301 | 3606946 | Ferrite bead | 0.2r 26r/ | 100mhz 1206 |
| L360 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L302 | 3606946 | Ferrite bead | 0.2r 26r/ | 100mhz 1206 |
| L400 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L303 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L401 3640011 Filter z>600r/100m 0r6max 0.2a 0805 L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L360 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L431 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L400 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| | L401 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| L441 3640011 Filter z>600r/100m 0r6max 0.2a 0805 | L431 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |
| | L441 | 3640011 | Filter | z>600r/1 | 00m 0r6max 0.2a 0805 |

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|----------|-----------|----------------|------------------------------------|
| L451 | 3640011 | Filter | z>600r/100m 0r6max 0.2a 0805 |
| L452 | 3640011 | Filter | z>600r/100m 0r6max 0.2a 0805 |
| L511 | | Chip coil | 120 n 10 % Q=35/150 MHz 0805 |
| L532 | | Chip coil | 330 n 5 % Q=33/50 MHz 1206 |
| L541 | 3641550 | Chip coil | 120 n 10 % Q=35/150 MHz 0805 |
| L542 | | Chip coil | 330 n 5 % Q=33/50 MHz 1206 |
| L543 | 3641560 | Chip coil | 220 n 10 % Q=30/100 MHz 0805 |
| L544 | 3641560 | Chip coil | 220 n 10 % Q=30/100 MHz 0805 |
| L545 | 3608326 | Chip coil | 330 n 5 % Q=33/50 MHz 1206 |
| L546 | | Chip coil | 330 n 5 % Q=33/50 MHz 1206 |
| L551 | 3641538 | Chip coil | 39 n 20 % Q=40/250 MHz 0805 |
| L710 | 3645025 | Chip coil | 220 n 10 % Q=20/25 MHz 0805 |
| L711 | 3641542 | Chip coil | 56 n 10 % Q=40/200 MHz 0805 |
| L760 | 3606946 | Ferrite bead | 0.2r 26r/100mhz 1206 |
| L800 | 3641324 | Chip coil | 10 u 10 % Q=25/2.52 MHz 1008 |
| L840 | 3641574 | Chip coil | 68 n 5 % Q=40/200 MHz 0805 |
| L841 | 3641538 | Chip coil | 39 n 20 % Q=40/250 MHz 0805 |
| B400 | 4510003 | Crystal | 32.768 k +-20PPM 8x3.8 |
| B800 | 4510075 | Crystal | 13.000 M +-5PPM |
| G810 | 4352933 | Vco | 1006-1031mhz4.5 15ma DCT2GSM |
| F100 | 5119002 | SM fuse | f2.0a 32v 1206 |
| Z500 | 4512046 | Dupl | 890-915/935-960mhz 37x14.7 |
| Z501 | 4511016 | Saw Filter | 947.5+–12.5 M 5.4x5.2 |
| Z505 | 4511016 | Saw Filter | 947.5+–12.5 M 5.4x5.2 |
| Z541 | 4511026 | Saw Filter | 71+–0.08 M 14.2x8.4 |
| Z551 | 4510009 | Cer.Filter | 13+-0.09mhz 7.2x3.2 |
| Z713 | 4550101 | Cer.Filter | 902.5+-12.5mhz 9.4x8.9 |
| V101 | 4110053 | Trans. supr. | 82V (SMB)DO214AA |
| V102 | 4110053 | Trans. supr. | 82V (SMB)DO214AA |
| V103 | 4110053 | Trans. supr. | 82V (SMB)DO214AA |
| V104 | 4110053 | Trans. supr. | 82V (SMB)DO214AA |
| V121 | 4110074 | Schottky diode | STPS340U 40 V 3 A SOD6 |
| V122 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V123 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V125 | 4110015 | Trans. supr. | 8.2V 8.2 V DO214AA |
| V140 | 4211421 | MosFet | RF1S9 p-ch 20 V TO263 |
| V141 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V142 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V143 | 4115805 | Diode | ES1C ULTR A D0214AC |
| V146 | 4210106 | Transistor | BSR19 npn 14 V 0.6 A SOT23 |
| V170 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V202 | 4202671 | MosFet | BST82 n-ch 80 V 175 mA SOT23 |

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|----------|---------|----------------|------------------------------------|
| V203 | 4202671 | MosFet | BST82 n-ch 80 V 175 mA SOT23 |
| V205 | 4107160 | Zener diode | BZX84 5 % 12 V 0.3 W SOT23 |
| V206 | 4107160 | Zener diode | BZX84 5 % 12 V 0.3 W SOT23 |
| V212 | 4202671 | MosFet BST82 | n-ch 80 V 175 mA SOT23 |
| V213 | 4202671 | MosFet BST82 | n-ch 80 V 175 mA SOT23 |
| V215 | 4107160 | Zener diode | BZX84 5 % 12 V 0.3 W SOT23 |
| V216 | 4107160 | Zener diode | BZX84 5 % 12 V 0.3 W SOT23 |
| V221 | 4210106 | Transistor | BSR19 npn 14 V 0.6 A SOT23 |
| V222 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V223 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V224 | 4210106 | Transistor | BSR19 npn 14 V 0.6 A SOT23 |
| V225 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V226 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V240 | 4110072 | Diode x 2 | BAV99W 70 V 0.2 A SOT323 |
| V250 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V300 | 4210020 | Transistor | BCP69-25 pnp 20 V 1 A SOT223 |
| V302 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V303 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V304 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V341 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V404 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V422 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V423 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V424 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V425 | 4219926 | Tr+rx2 | rn1302 n50v50ma 10k SOT323 |
| V426 | | | Green 2.2 V 1206 |
| V427 | 4102998 | | Green 2.2 V 1206 |
| V428 | 4102998 | | Green 2.2 V 1206 |
| V429 | 4102998 | | Green 2.2 V 1206 |
| V430 | | Transistor | BSR20 pnp 12 V 0.6 A SOT23 |
| V431 | | Transistor | BSR20 pnp 12 V 0.6 A SOT23 |
| V501 | | Transistor | BFP420 npn 4. V SOT343 |
| V502 | | Transistor | BFP420 npn 4. V SOT343 |
| V503 | | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V504 | | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V505 | | Transistor | BC848W npn 30 V SOT323 |
| V506 | | Transistor | BC848W npn 30 V SOT323 |
| V511 | | Sch. diode x 2 | 4V 30 mA SOT23 |
| V512 | | Transistor | BFP182 npn 20 V 35 mA SOT143 |
| V541 | | Transistor | BFR93A npn 12 V 35 mA SOT323 |
| V601 | | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V701 | 4210066 | Transistor | BFR93AW npn 12 V 35 mA SOT323 |

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|---------|------------|-----------------|-------------------------------------|
| V702 | 4100567 | Sch. diode x 2 | BAS70–04 70V15 mA SERSOT23 |
| V720 | 4200755 | Transistor | BFR92A npn 15 V 25 mA SOT23 |
| V730 | 4200755 | Transistor | BFR92A npn 15 V 25 mA SOT23 |
| V731 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V740 | 4210090 | Transistor | BFG540/X npn 15 V 129 mA SOT143 |
| V741 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V750 | 4210133 | Transistor | BFG10W/X npn 10 V 0.25 A SOT343 |
| V751 | 4210102 | Transistor | BC858W pnp 30 V 100 mA 200MWSOT323 |
| V760 | 4210135 | Transistor | BLT82 npn 10 V SO8S |
| V761 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V772 | 4217070 | Transistor x 2 | IMD |
| V773 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V775 | 4210100 | Transistor | BC848W npn 30 V SOT323 |
| V781 | 4110014 | Sch. diode x 2 | BAS70-07 70 V 15 mA SOT143 |
| V791 | 4100285 | Diode x 2 | BAV99 70 V 200 mA SER.SOT23 |
| V800 | 4111092 | Cap. diode | BB639 30 V SOD323 |
| V801 | 4210066 | Transistor | BFR93AW npn 12 V 35 mA SOT323 |
| V802 | 4210066 | Transistor | BFR93AW npn 12 V 35 mA SOT323 |
| V840 | 4110018 | Cap. diode | BB135 30 V SOD323 |
| V841 | 4210066 | Transistor | BFR93AW npn 12 V 35 mA SOT323 |
| V842 | 4210066 | Transistor | BFR93AW npn 12 V 35 mA SOT323 |
| D360 | 4370297 | IC, | tms320lc546 3v wd5 DSP TQFP100 |
| D400 | 4370101 | IC | Cf70131 gsm/pcn asic bart QFP144 |
| D420 | 4340307 | IC | MCU TQFP80 |
| D430 | 4340217 | IC | Te28f008s3 flash 3.3v 1mx8 TSOP40 |
| D440 | 4340315 | IC, | SRAM TSO32 |
| D445 | 4342264 | IC | EEPROM SO8S |
| N130 | 4370301 | IC | St5092 pcm codec/Filterer SO28 |
| N140 | 4305236 | IC, | 2 x comp. LM2903 SO8S |
| N250 | 4340215 | IC | Am79r79 subscrib.interface PLCC32 |
| N300 | 4370223 | IC | Stt261c pscld_e pw supply TQFP44 |
| N350 | 4301062 | IC | regulator LP2951AC SO8S |
| N450 | 4370097 | IC | St7523 rfi2 v4.2 tdma codec QFP64 |
| N551 | 4370243 | IC | Crfrt_st tx.mod+rxif+pwc SQFP44 |
| N601 | 4370095 | IC | Crfcontf 8xreg4.5v vref2v5 VSOP28 |
| N820 | 4340005 | IC, | 2xsynth 1.2ghz 3v UMA1018M SSO20 |
| X100 | 5409043 | SM, | modular jack 6pol right angl |
| X101 | 5409043 | SM, | modular jack 6pol right angl |
| X110 | 5414943 | Dc-jack | d6.3/2 pcb |
| X120 | 541Y001 | PCB connector | 2x10 2.54p horizont.smdHORIZONT.SMD |
| X300 | 5408807 | Sim card reader | ccm04-5002 2x 3CO2x3con |
| X500 | 5420011 | Connector | mini uhf 90'deg <2.5gh <2.5GHZ |

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X510 5420011 Connector 9854269 PCB mini uhf 90'deg <2.5gh

<2.5GHZ

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